

PAH200S48-*

**QUALITY
TEST DATA**



POWER MODULE

DRAWING NO. : PA554-53-01			
DLJ QA	NLS R&D		
APPROVED	PREPARED	CHECKED	APPROVED
<i>Parvathy</i>	<i>AG</i> 24/7/2020	<i>A</i> 24/7/2020	<i>JSS</i> 24/7/2020
DATE : 24/5/2020	DATE ISSUE : 24 July 2020		

NEMIC-LAMBDA (S) PTE LTD

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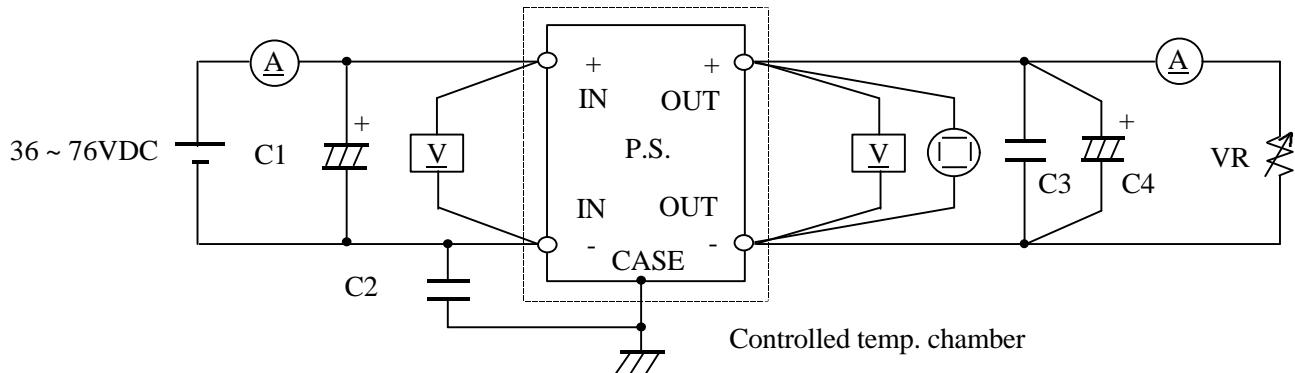
Terminology used

Vin -	Input Voltage	Iout -	Output Current
Vout -	Output Voltage	Tp -	Base-Plate Temperature
Iin -	Input Current	Tr -	Load Rise-Time
		Tf -	Load Fall-Time

1. EVALUATION METHOD

1 - 1 Circuit used for determination

(1) Steady state data



(i) $T_p = -20^\circ\text{C} \sim 100^\circ\text{C}$

C1 : 33 μF Electrolytic Capacitor

C2 : 4700pF Ceramic Capacitor

C3 : 1 μF Ceramic Capacitor

C4 : 12V&15V - 1000 μF Electrolytic Capacitor

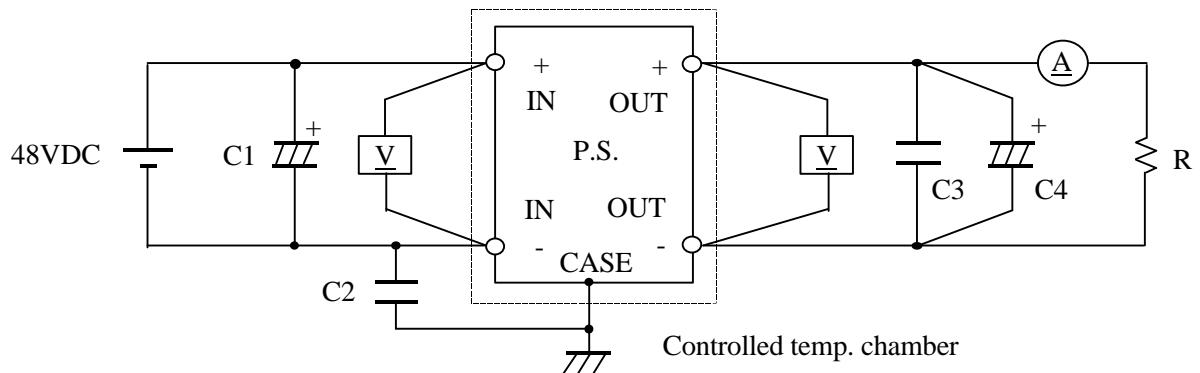
24V&28V - 470 μF Electrolytic Capacitor

(ii) $T_p = -40^\circ\text{C} \sim 100^\circ\text{C}$

C1 : 33 μF Ceramic Capacitor or equivalent capacitor such as 100V 6.8 μF x 5 pcs

C4 : 2 pieces of the above recommended value

(2) Warm up voltage drift characteristics



C1 : 33 μF Electrolytic Capacitor

C2 : 4700pF Ceramic Capacitor

C3 : 1 μF Ceramic Capacitor

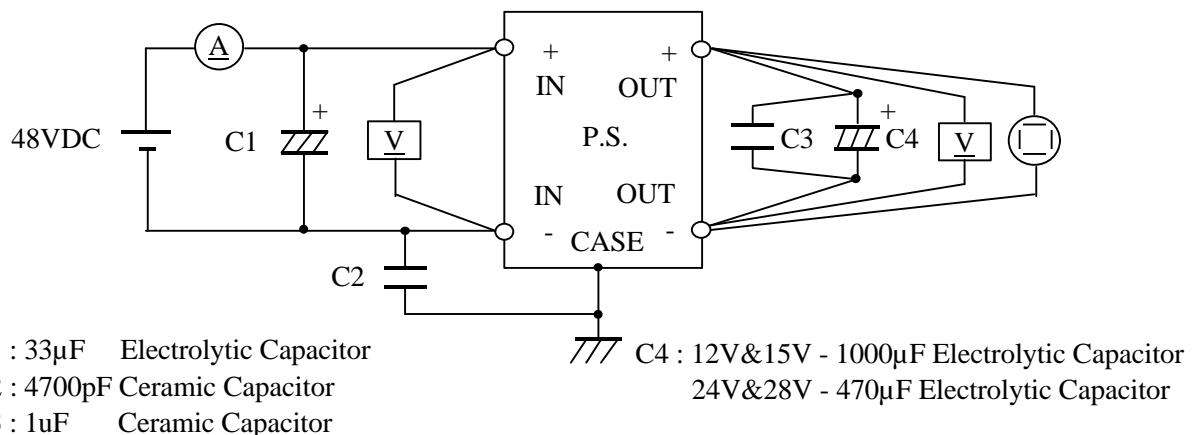
C4 : 12V&15V - 1000 μF Electrolytic Capacitor

24V&28V - 470 μF Electrolytic Capacitor

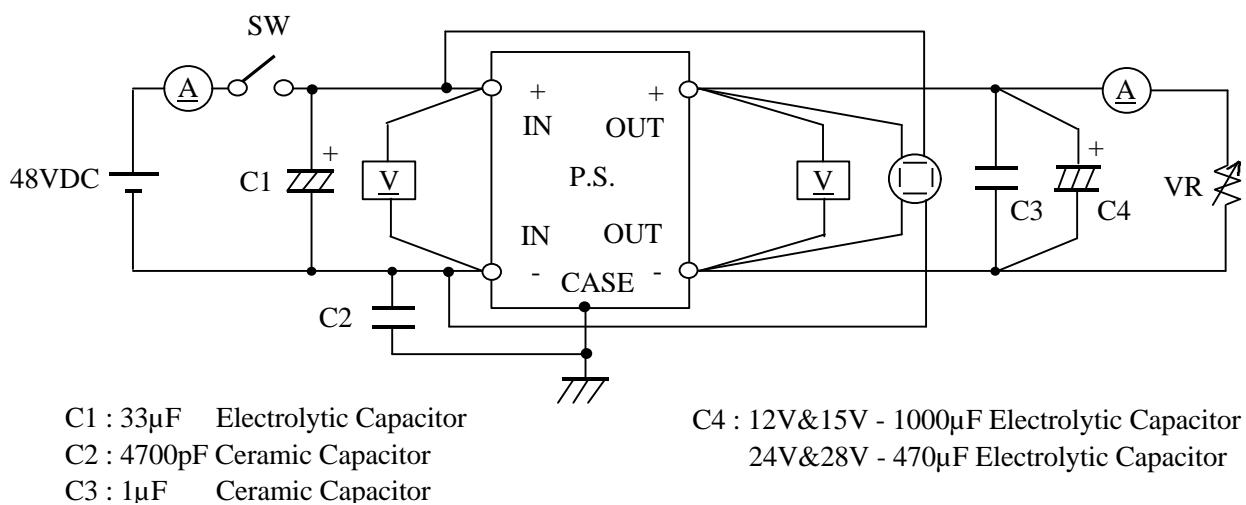
(3) Over current protection (O.C.P.) characteristics

Same as steady state data

(4) Over voltage protection (O.V.P.) characteristics



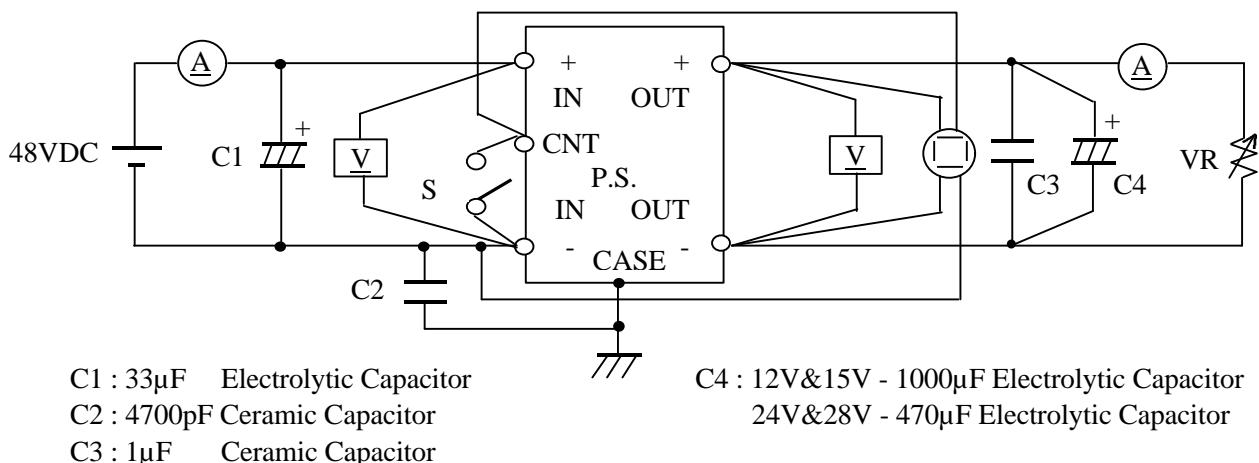
(5) Output rise characteristics



(6) Output fall characteristics

Same as Output rise characteristics

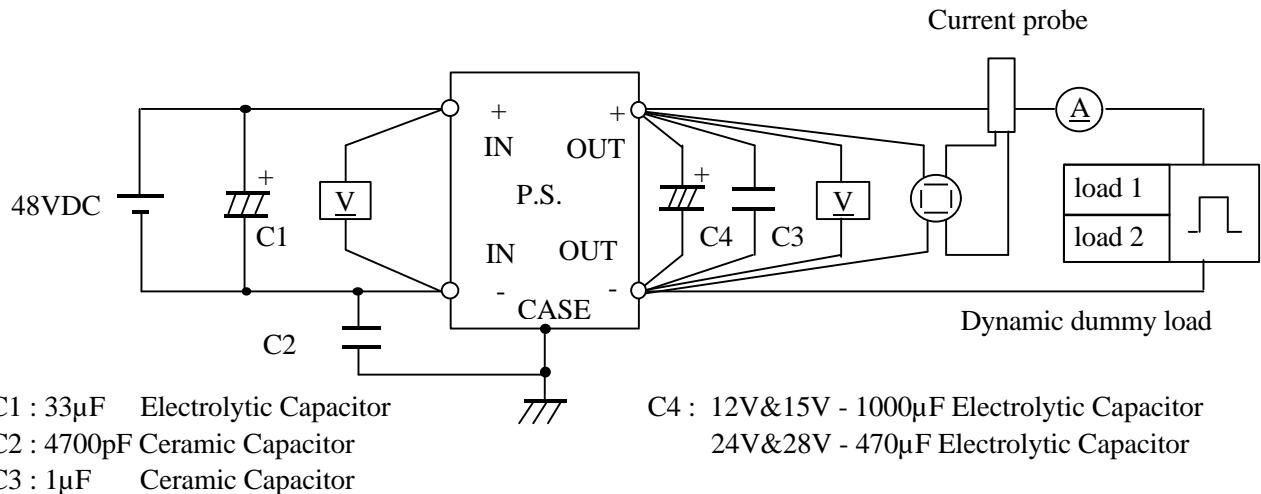
(7) Output rise characteristics with on/off control



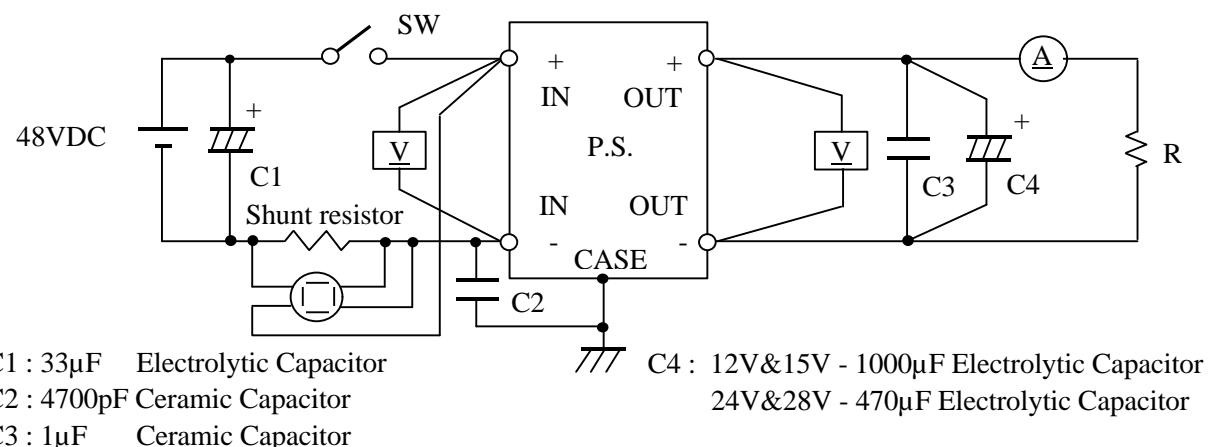
(8) Output fall characteristics with on/off control

Same as Output rise characteristics with on/off control

(9) Dynamic load response characteristics

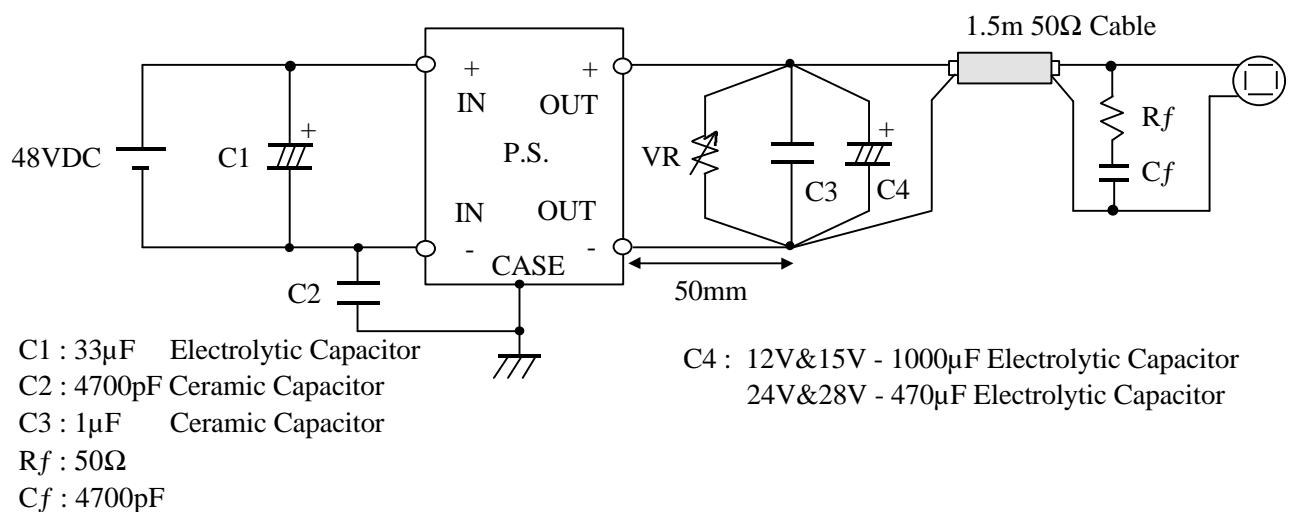


(10) Inrush current waveform



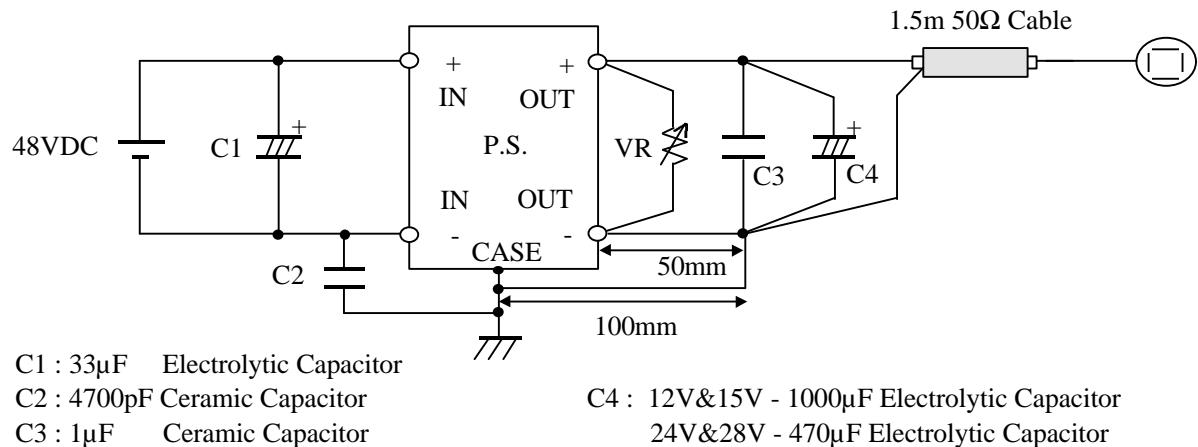
(11) Output-ripple , noise waveform

NORMAL MODE (EIAJ Standard RC-9002A)

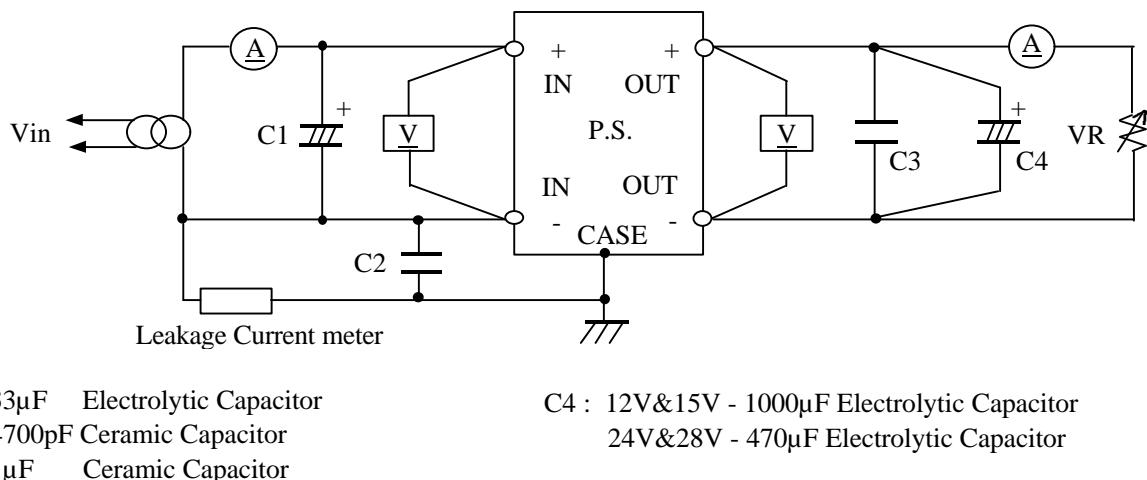


(11) Output-ripple , noise waveform

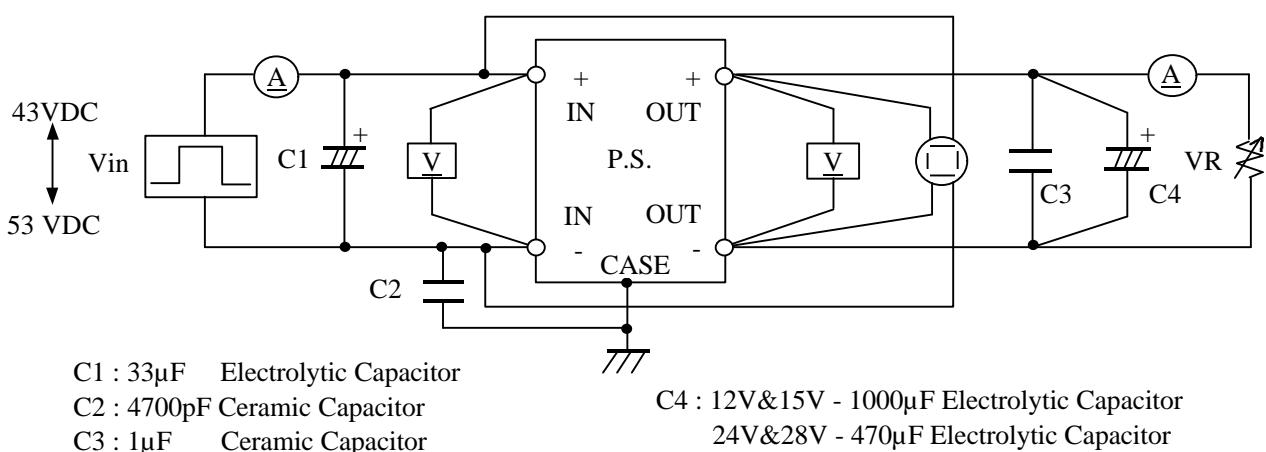
NORMAL + COMMON MODE



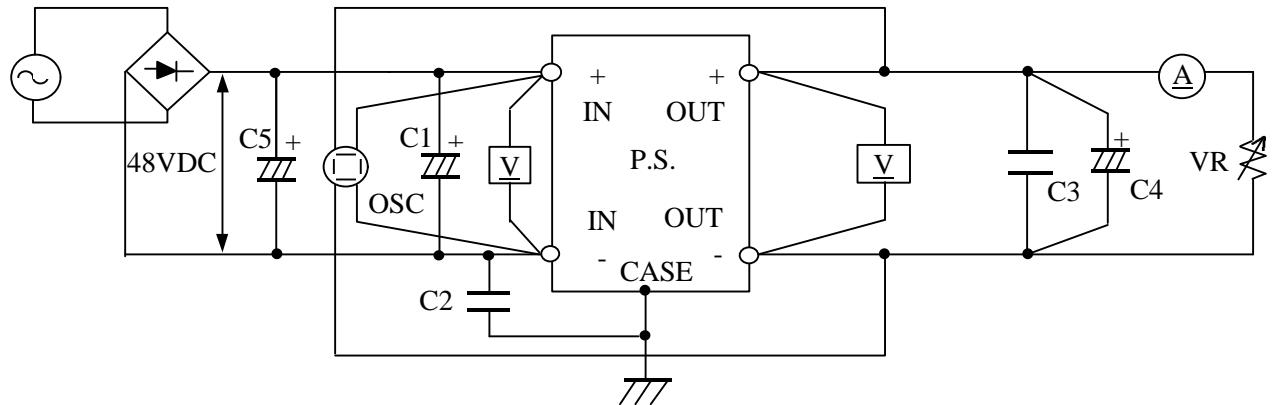
(12) Leakage current characteristics



(13) Dynamic line characteristics



(14) AC input response characteristics



C1 : 33μF Electrolytic Capacitor

C2 : 4700pF Ceramic Capacitor

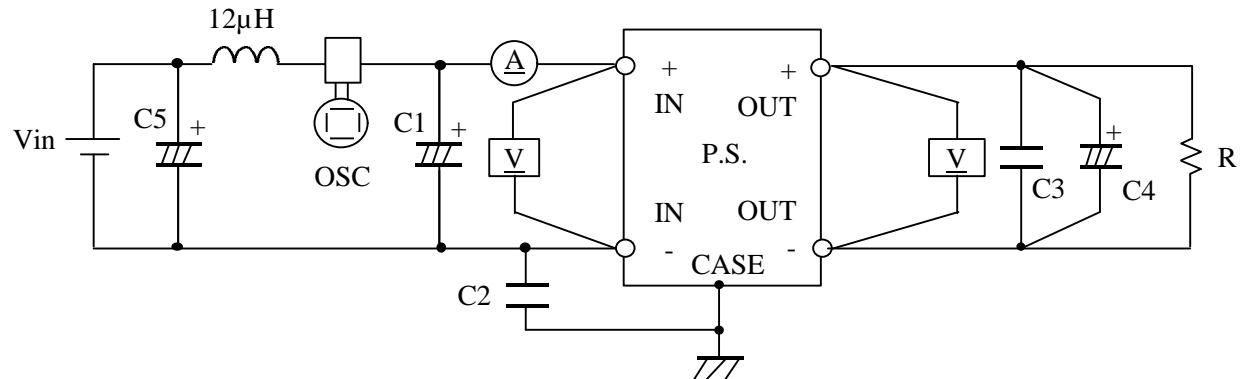
C3 : 1μF Ceramic Capacitor

C5 : 560μF Electrolytic Capacitor

C4 : 12V&15V - 1000μF Electrolytic Capacitor

24V&28V - 470μF Electrolytic Capacitor

(15) Input Reflected current characteristics



C1 : 33μF Electrolytic Capacitor

C2 : 4700pF Ceramic Capacitor

C3 : 1μF Ceramic Capacitor

C5 : 220μF Electrolytic Capacitor

C4 : 12V&15V - 1000μF Electrolytic Capacitor

24V&28V - 470μF Electrolytic Capacitor

1-2 List of equipment used

No	Description	Manufacturer	Model No.
1	Oscilloscope	TEKTRONIX	2465B
2		HITACHI	V-1050F
3	Digital oscilloscope	YEW	DL2140
4		HITACHI	VC-6041
5	Digital volt meter	IWATSU	VDAC 7411
6	DC ampere meter	YOKOGAWA ELEC.	2051
7	Dynamic dummy load	TAKAMIZAWA	PSA-150D
8	Variable resistive load	MATSUNAGA	44/11Ω
9	Variable resistive load	MATSUNAGA	2.4/0.6Ω
10	Controlled temp . chamber	TABAI	PL-2GM
11	Shunt resistor	KUWANO	100mV , 1A
12	Current probe amplifier	TEKTRONIX	TM503
13	Current probe	TEKTRONIX	A6303
14	AC power source / Analyzer	HEWLETT PACKARD	6813A
15	Leakage current tester	SIMPSON	229-2

2. CHARACTERISTICS**2-1 Steady State Data**

(1) Regulation - Line and Load, Temperature Drift

12 V		Regulation - Line and Load				T _p = 25°C
I _{out}	V _{in}	36 VDC	48 VDC	76 VDC	Line Regulation (mV)	
0%	12.0530	12.0540	12.0540	1.0	0.008%	
50%	12.0510	12.0520	12.0520	1.0	0.008%	
100%	12.0500	12.0500	12.0510	1.0	0.008%	
Load Regulation (mV)	3.0	4.0	3.0			
	0.025%	0.033%	0.025%			

Temperature Drift

V_{in} = 48VDCI_{out} = 100%

T _p	-40°C	25°C	100°C	Temp. Stability	
V _{out}	12.030V	12.050 V	11.950 V	0.08	0.66%

24 V

Regulation - Line and Load

T_p = 25°C

I _{out}	V _{in}	36 VDC	48 VDC	76 VDC	Line Regulation (mV)
0%	24.01	24.003	24.009	7.0	0.029%
50%	24.004	24.004	23.995	9.0	0.037%
100%	23.987	23.997	23.994	10.0	0.042%
Load Regulation (mV)	23.0	7.0	15.0		
	0.096%	0.029%	0.062%		

Temperature Drift

V_{in} = 48VDCI_{out} = 100%

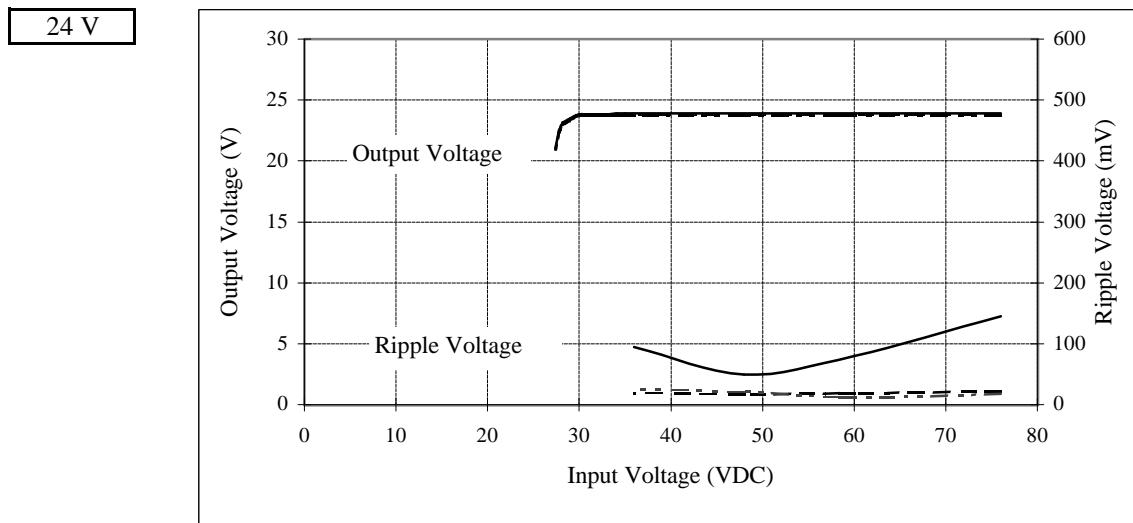
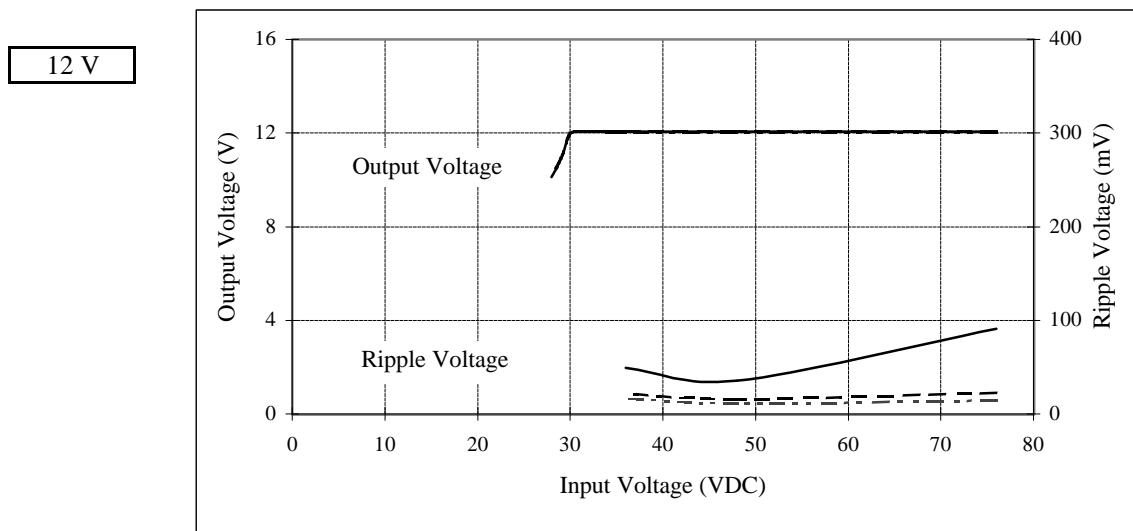
T _p	-40°C	25°C	100°C	Temp. Stability	
V _{out}	23.977 V	23.997 V	23.879 V	0.098 V	0.41%

2. CHARACTERISTICS

2-1 Steady State Data

(2) Output Voltage And Ripple Voltage V.S. Input Voltage

Condition : $I_{out} = 100\%$
 $T_p = -40^\circ C$ ———
 $T_p = 25^\circ C$ - - - -
 $T_p = 100^\circ C$ - · - - -

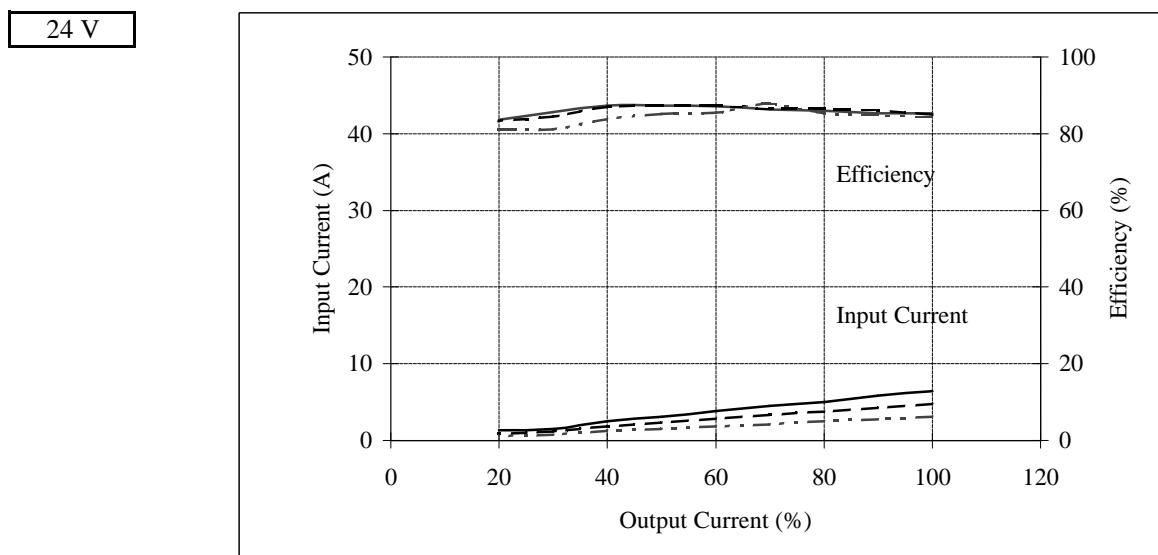
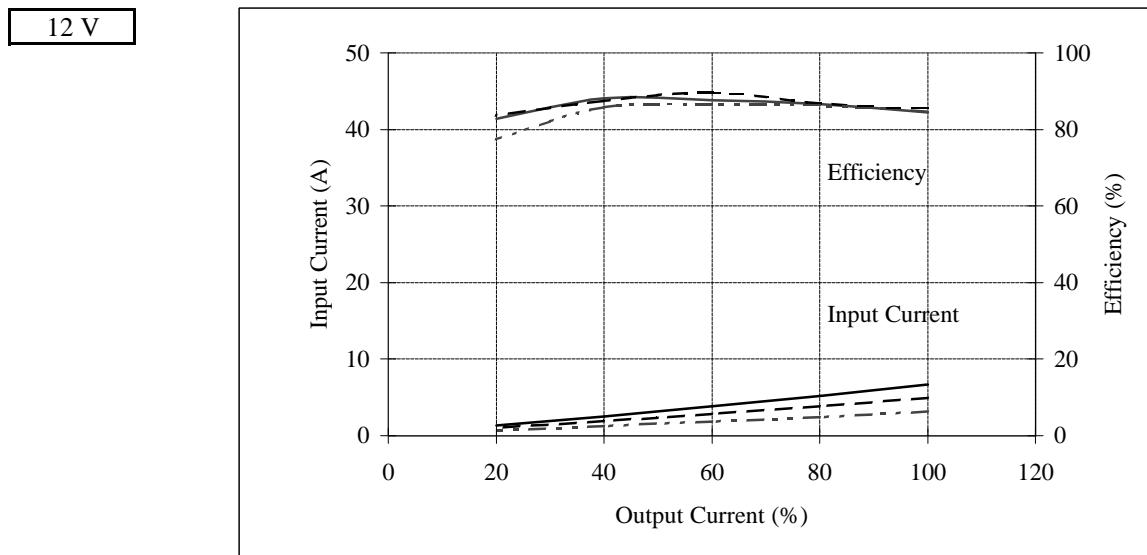


2. CHARACTERISTICS

2-1 Steady State Data

(3) Efficiency And Input Current V.S. Output Current

Condition : Vin = 36 VDC ———
 = 48VDC -----
 = 76VDC -·-----
 Tp = 25°C



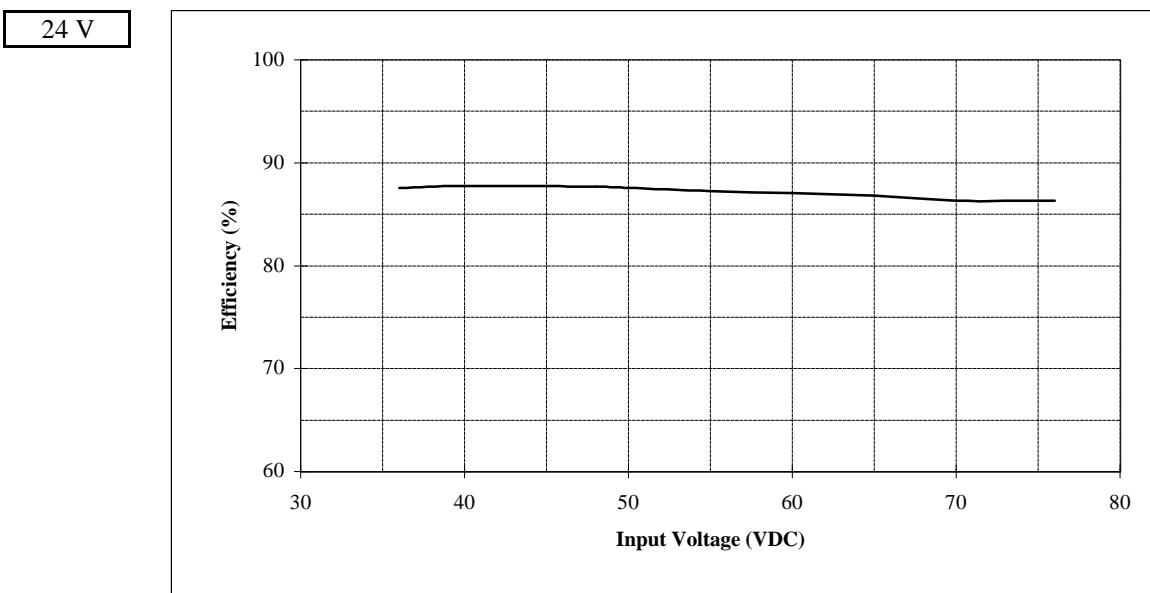
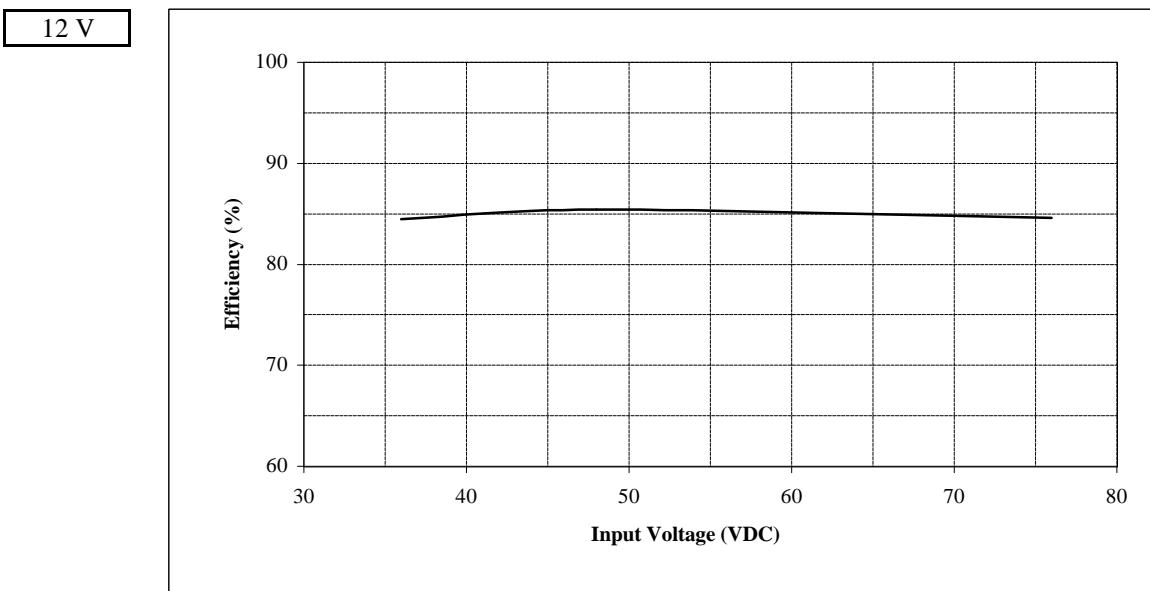
2. CHARACTERISTICS

2-1 Steady State Data

(4) Efficiency v.s. Input Voltage

Condition : $I_{out} = 100\%$

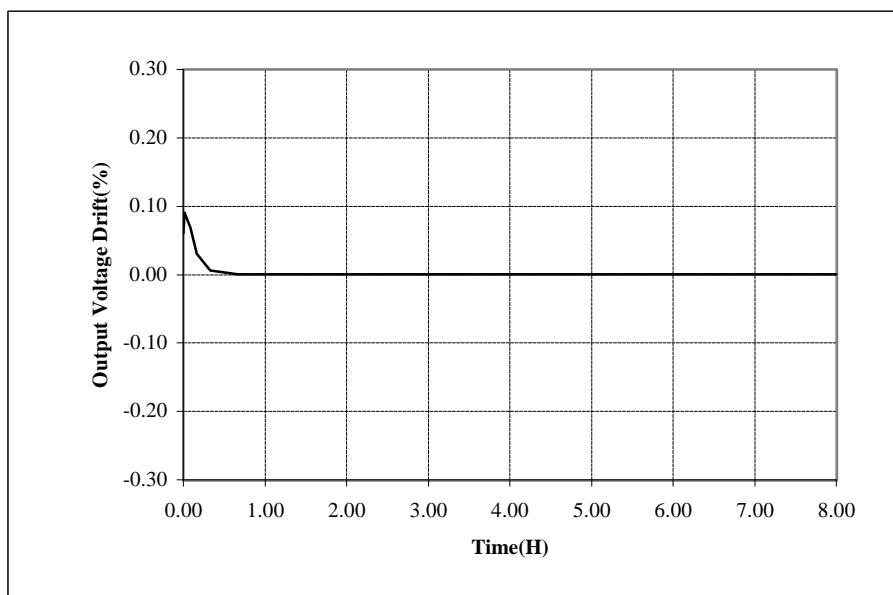
$T_p = 25^\circ C$



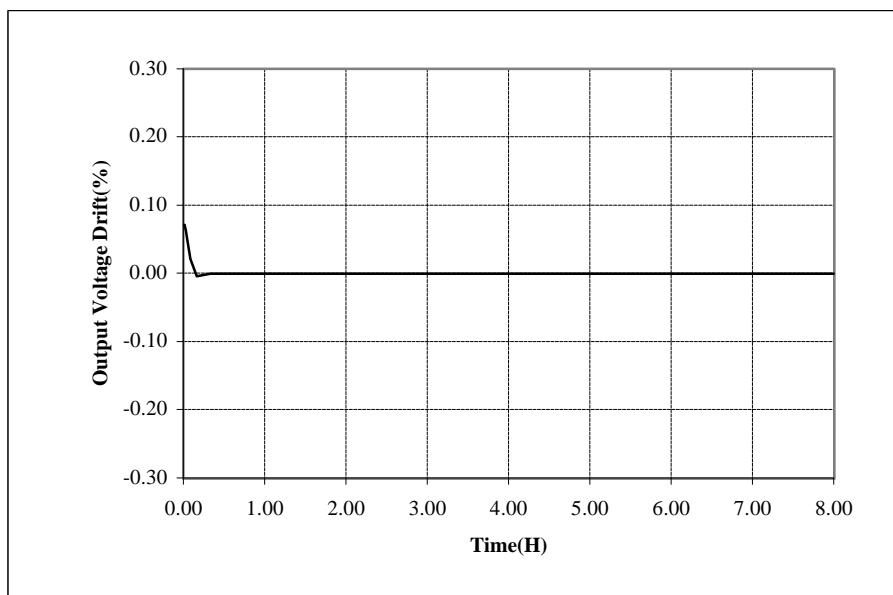
2-2 Warm Up Voltage Drift Characteristics

Condition : $V_{in} = 48 \text{ V DC}$
 $I_{out} = 100 \%$
 $T_p = 25^\circ\text{C}$

12 V



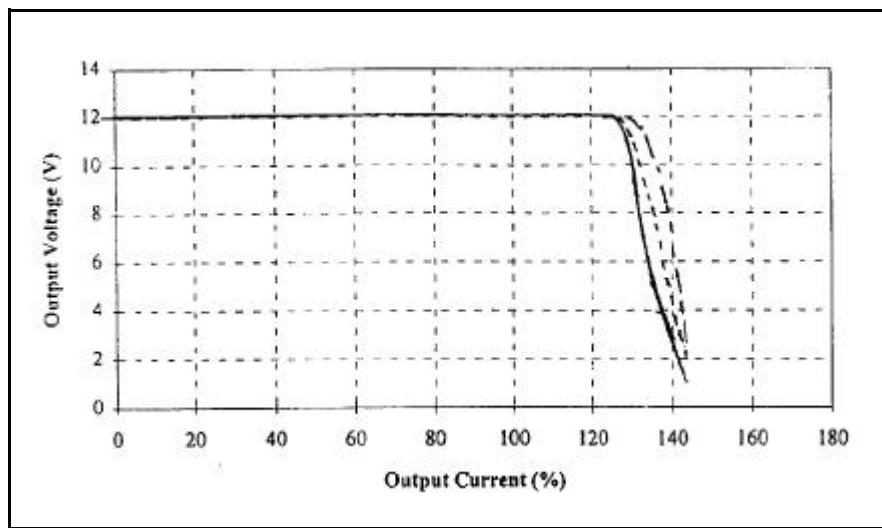
24 V



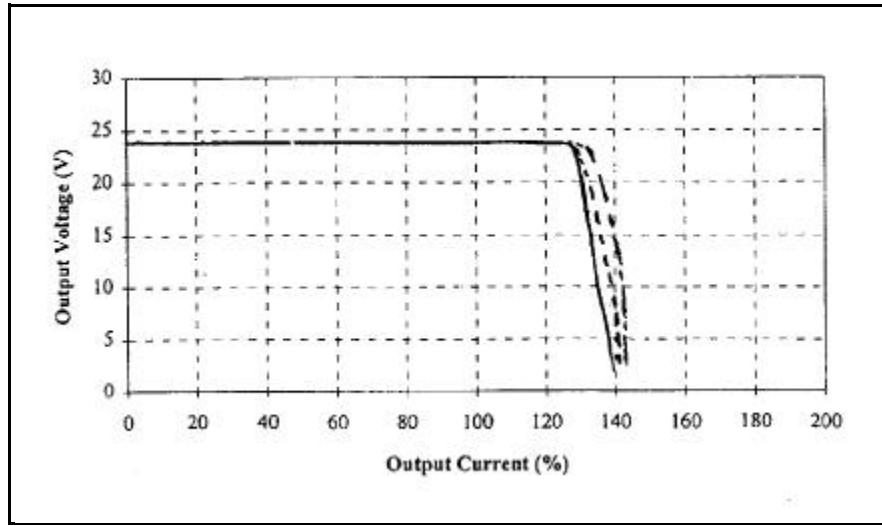
2-3 O.C.P. Characteristics

Condition : Vin = 36 VDC _____
Vin = 48 VDC -----
Vin = 76 VDC - - - - -
Tp = 25°C

12V



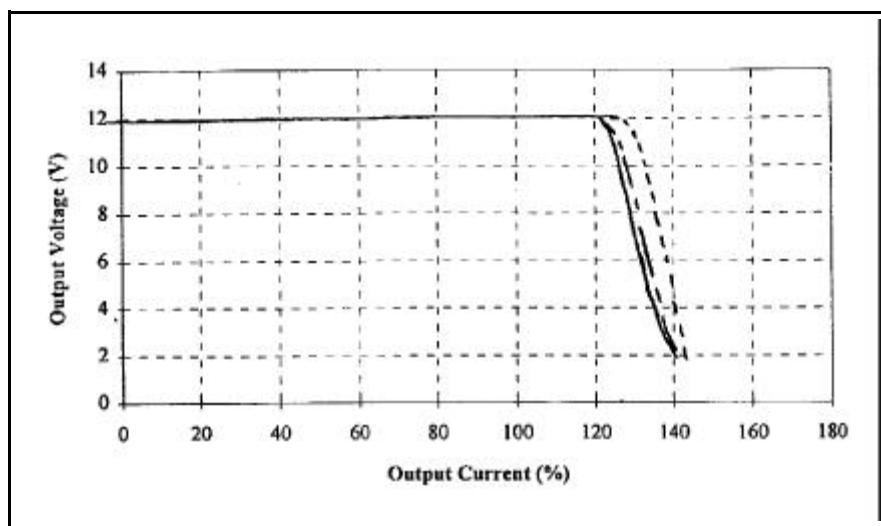
24V



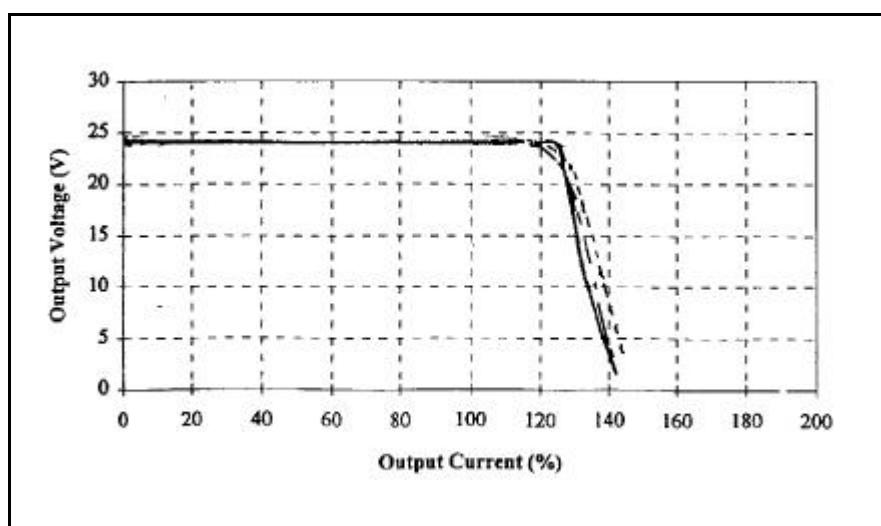
O.C.P. Characteristics

Condition :
Tp = -40°C ———
Tp = 25°C -----
Tp = 100°C - - - - -
Vin = 48 VDC

12V

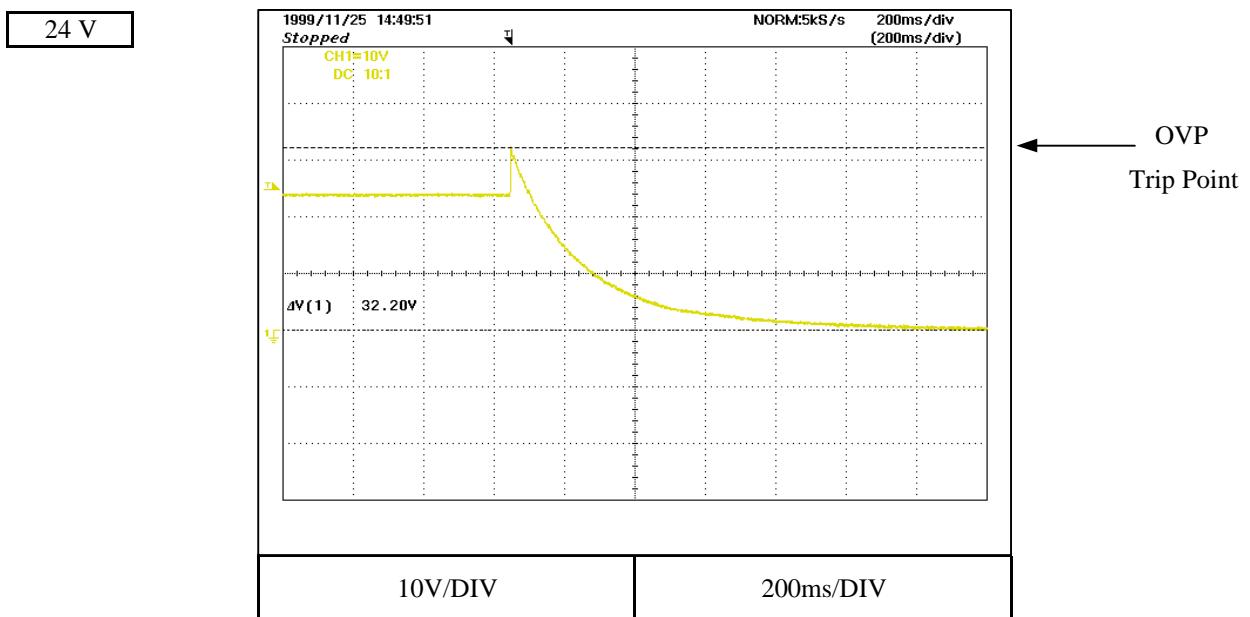
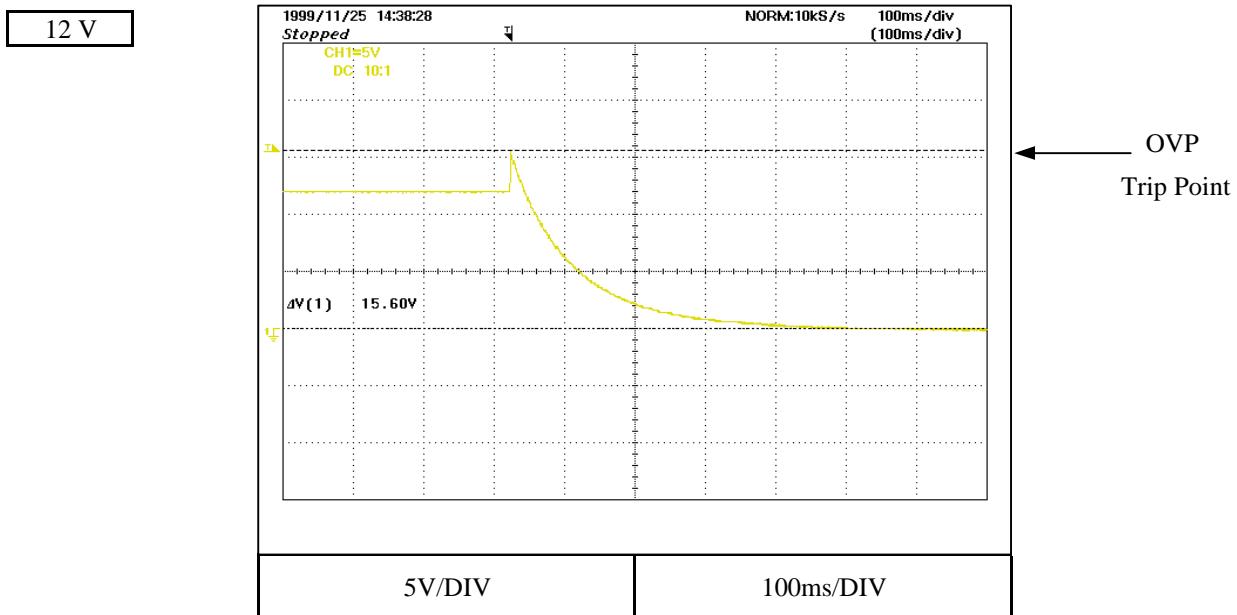


24V



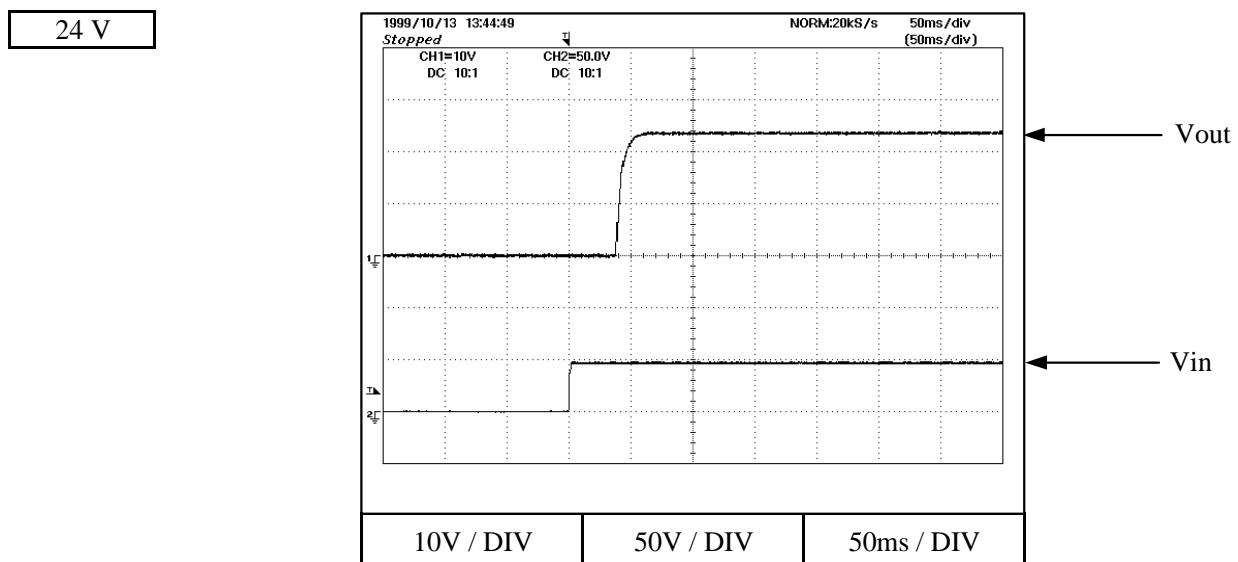
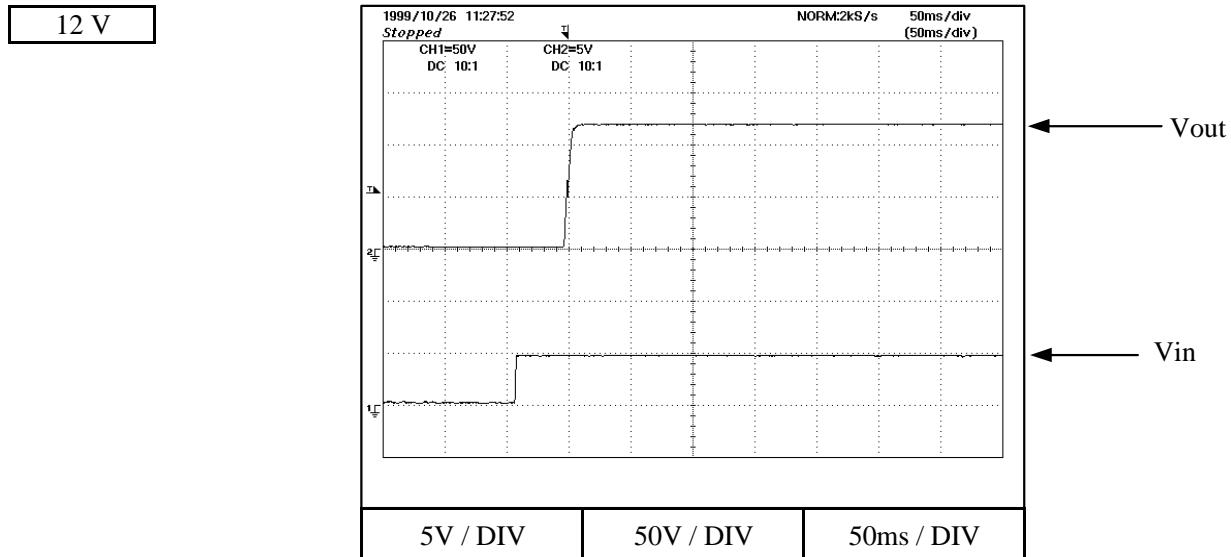
2-4 O.V.P. Characteristics

Condition : Vin = 48 V DC
 Iout = 0 %
 Tp = 25°C



2-5 Output Rise Characteristics

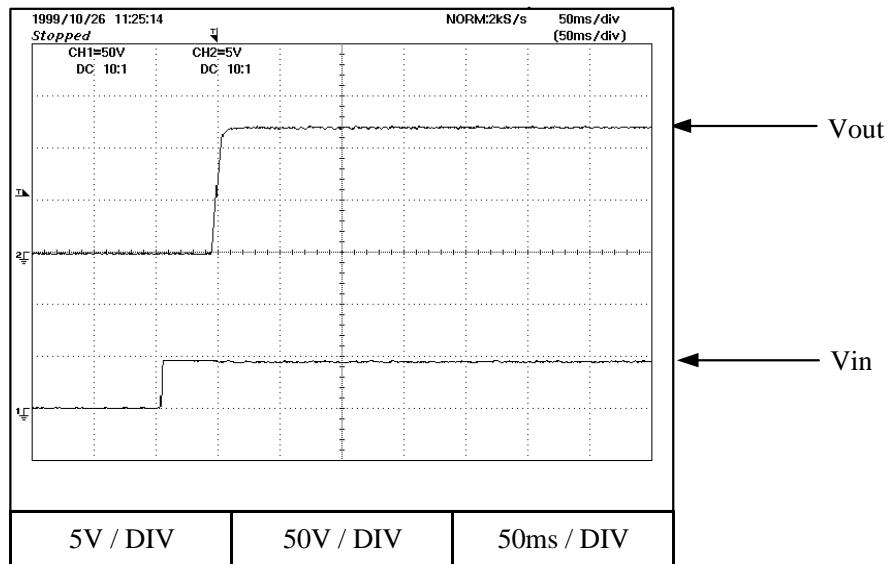
Condition : $V_{in} = 48 \text{ V DC}$
 $I_{out} = 0 \%$
 $T_p = 25^\circ\text{C}$



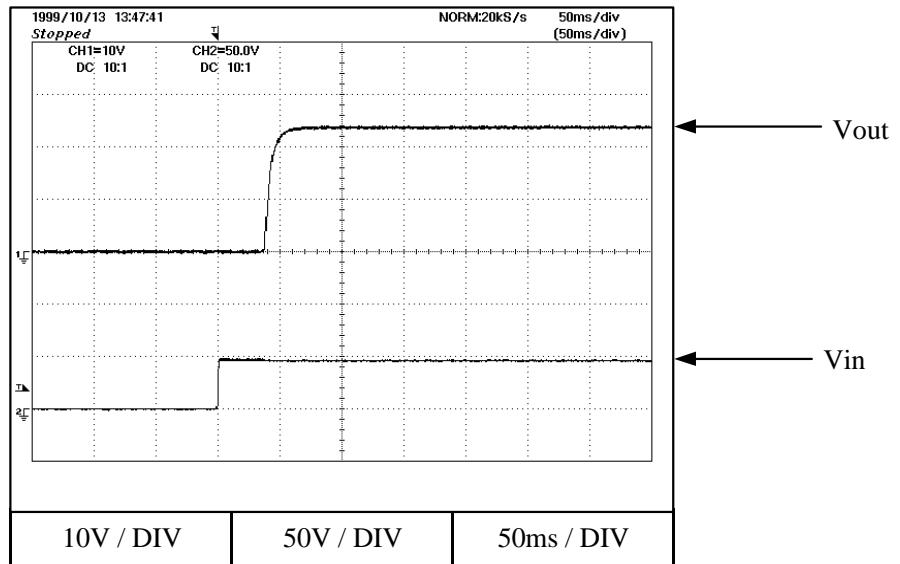
Output Rise Characteristics

Condition : Vin = 48 V DC
Iout = 100 %
Tp = 25°C

12 V

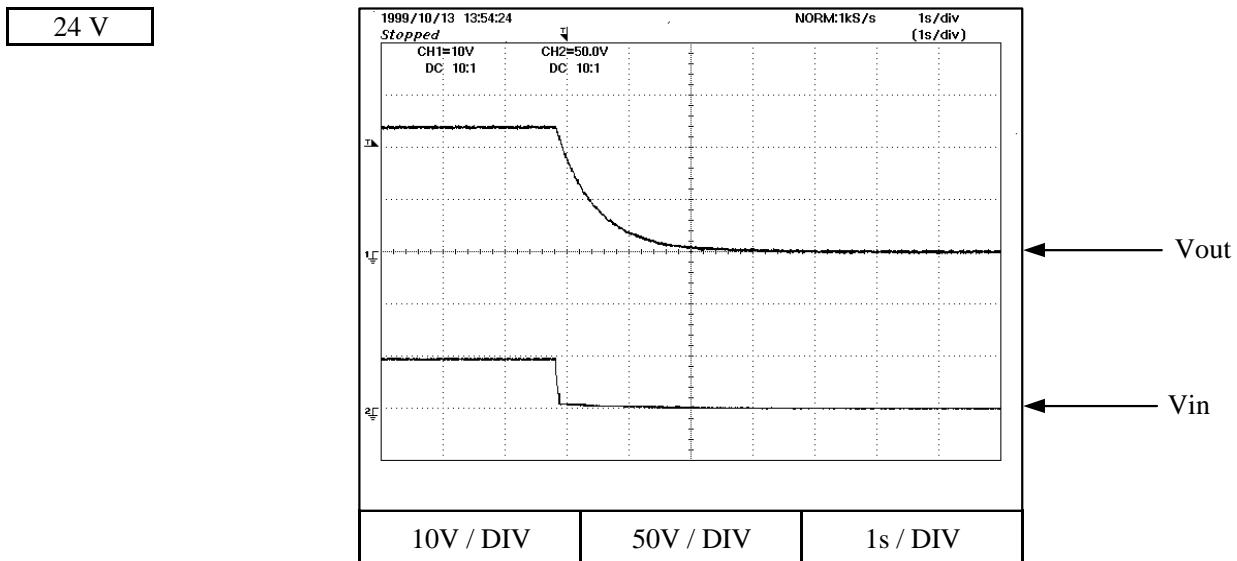
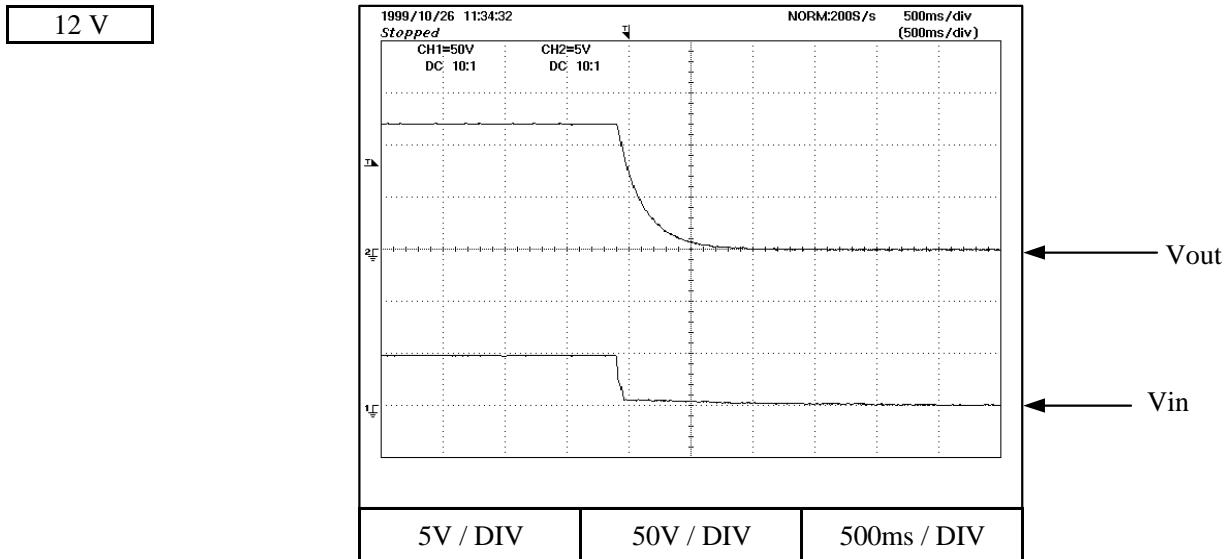


24 V



2-6 Output Fall Characteristics

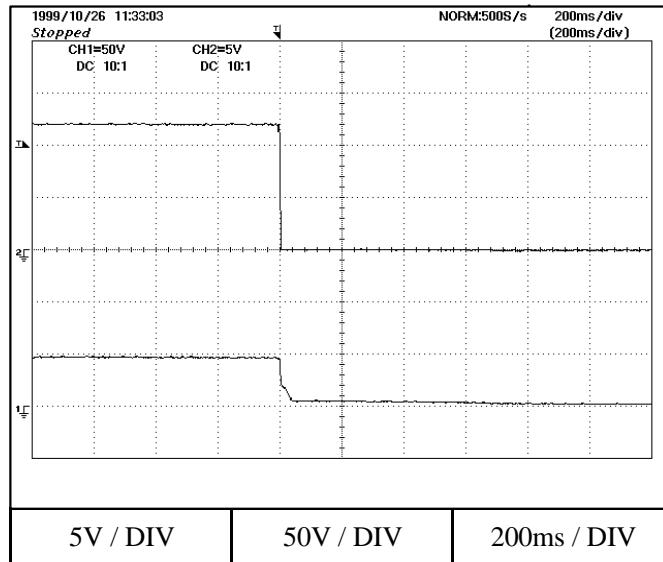
Condition : Vin = 48 V DC
Iout = 0 %
Tp = 25°C



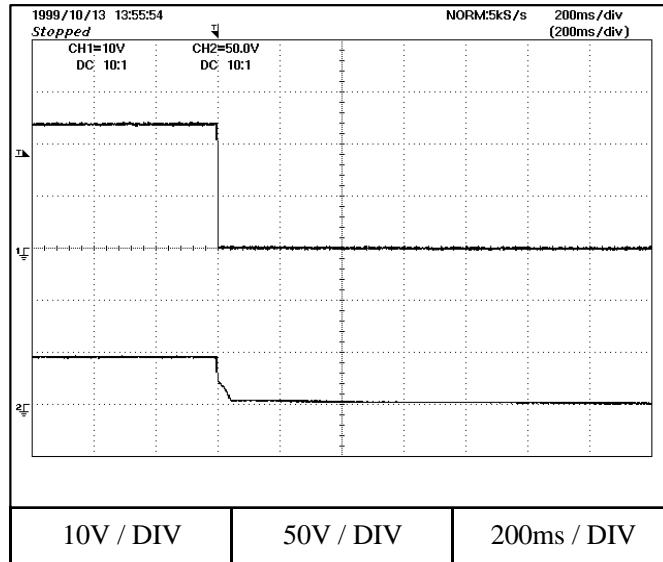
Output Fall Characteristics

Condition : Vin = 48 V DC
Iout = 100 %
Tp = 25°C

12 V



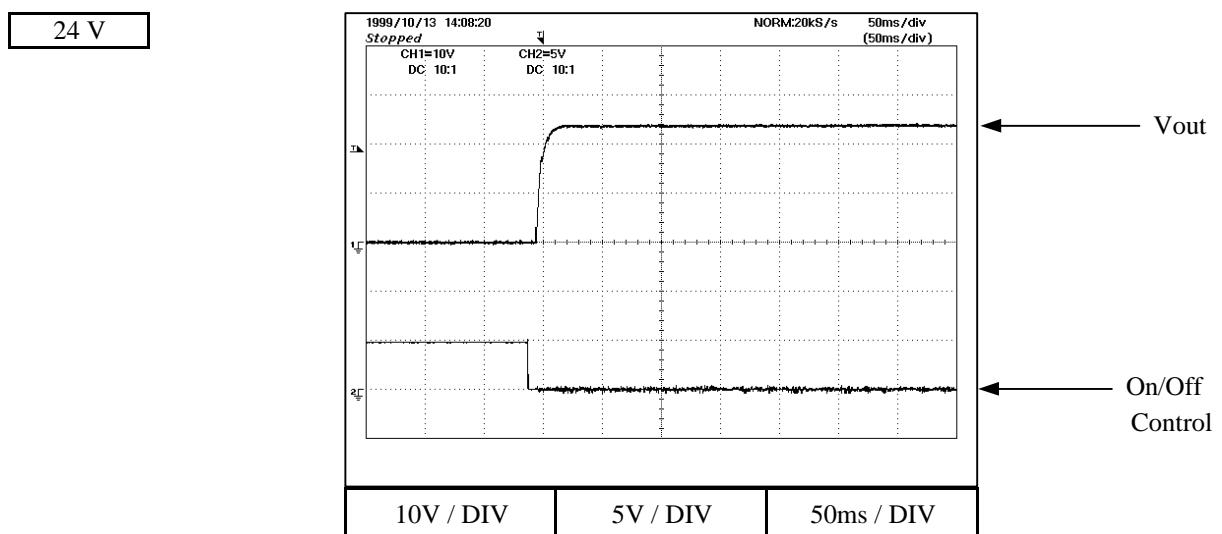
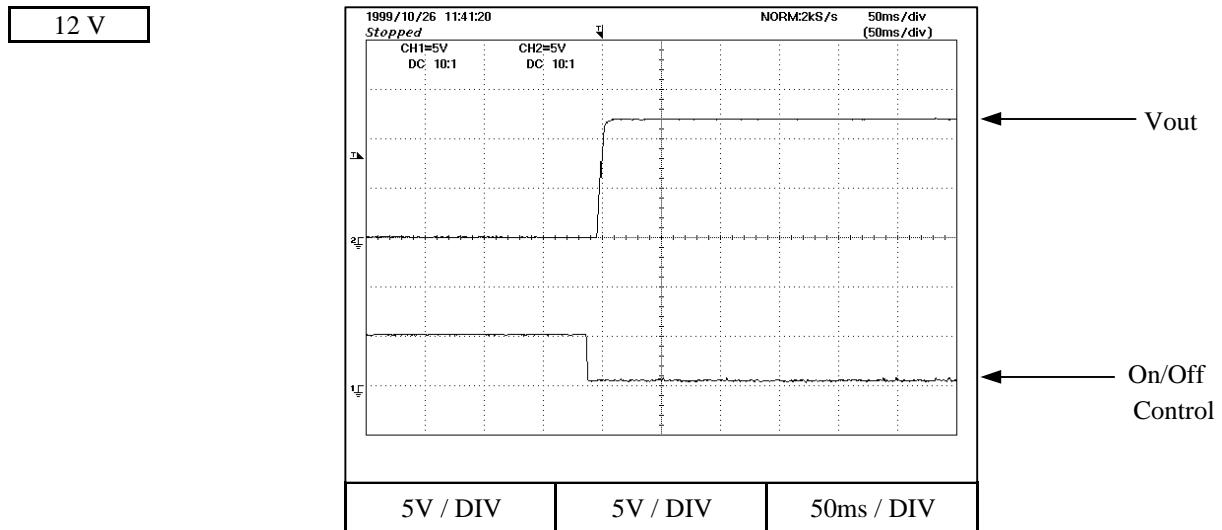
24 V



2-7 Output Rise With On/Off Characteristics

(Negative logic)

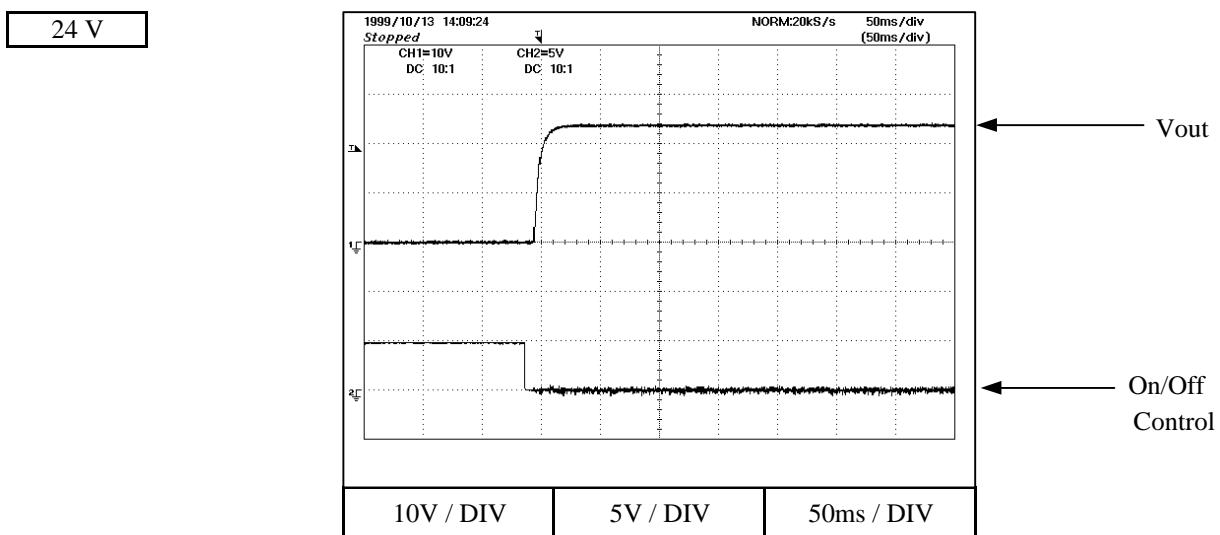
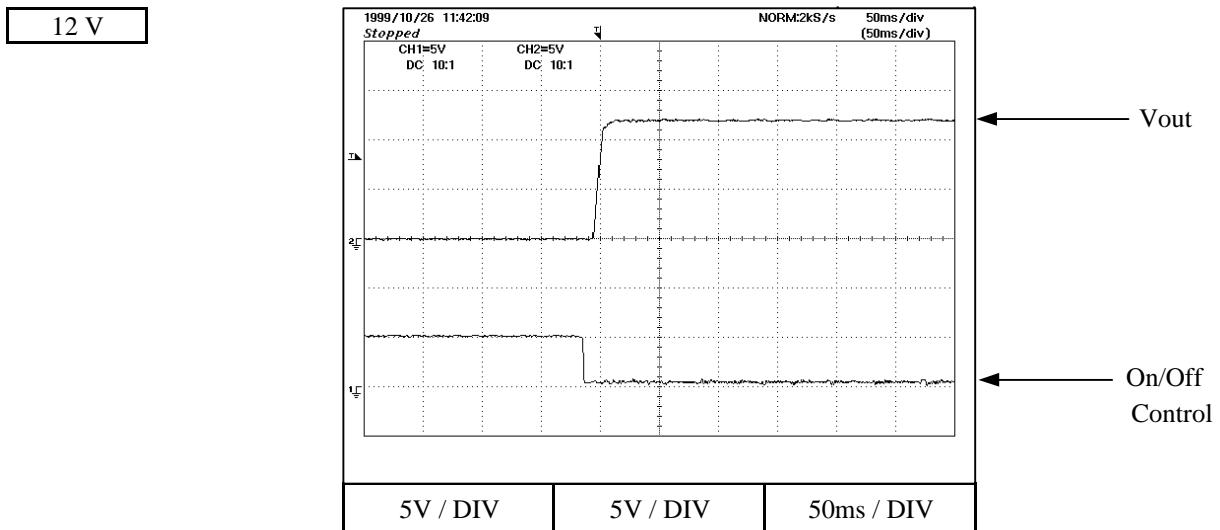
Condition : $V_{in} = 48 \text{ V DC}$
 $I_{out} = 0 \%$
 $T_p = 25^\circ\text{C}$



Output Rise With On/Off Characteristics

(Negative logic)

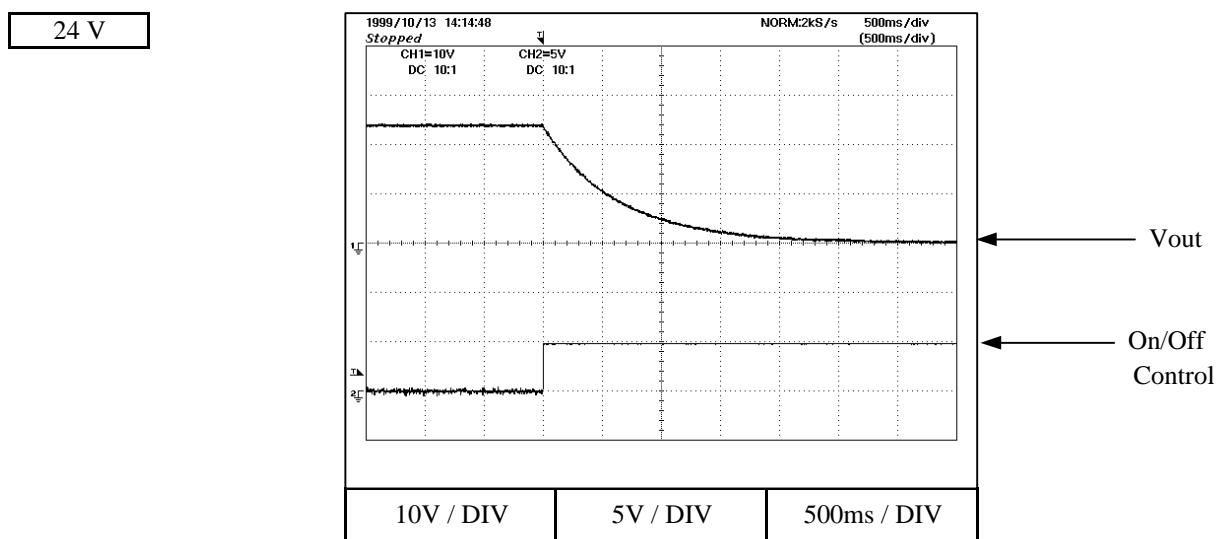
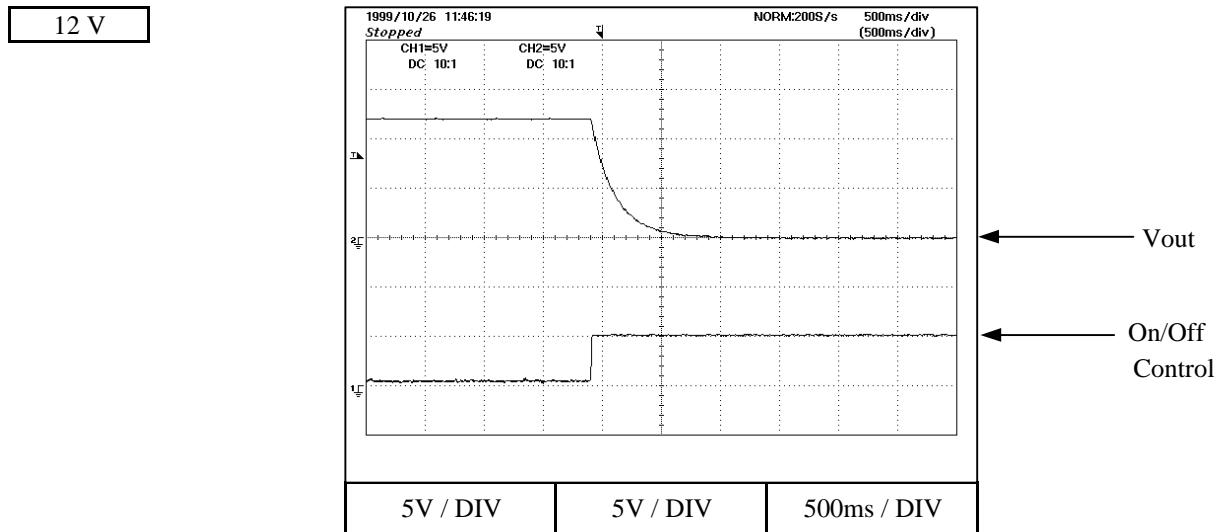
Condition : $V_{in} = 48 \text{ V DC}$
 $I_{out} = 100 \%$
 $T_p = 25^\circ\text{C}$



2-8 Output Fall With On/Off Characteristics

(Negative logic)

Condition : $V_{in} = 48 \text{ V DC}$
 $I_{out} = 0 \%$
 $T_p = 25^\circ\text{C}$



Output Fall With On/Off Characteristics

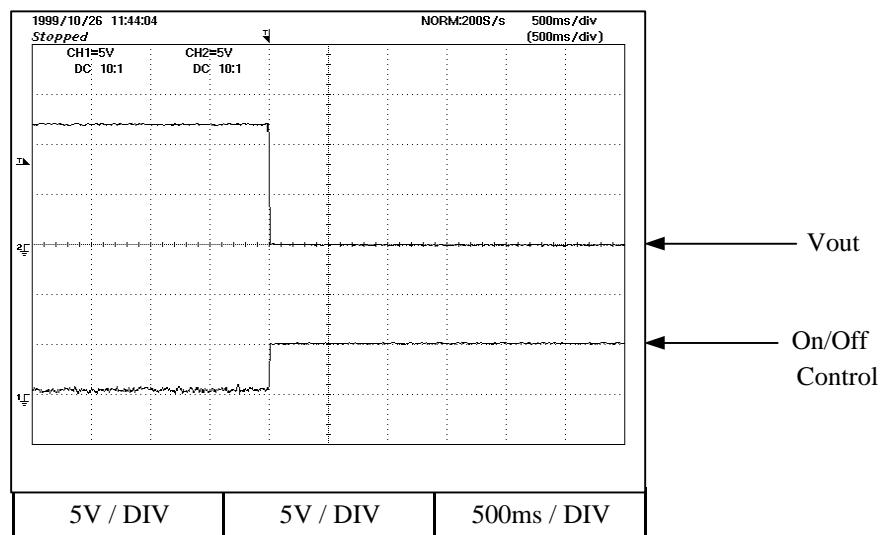
(Negative logic)

Condition : Vin = 48 V DC

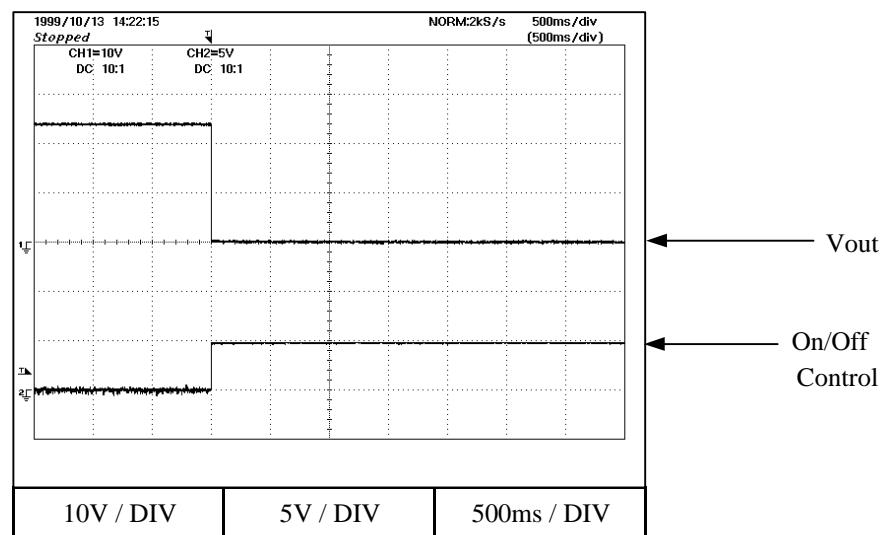
Iout = 100 %

Tp = 25°C

12 V

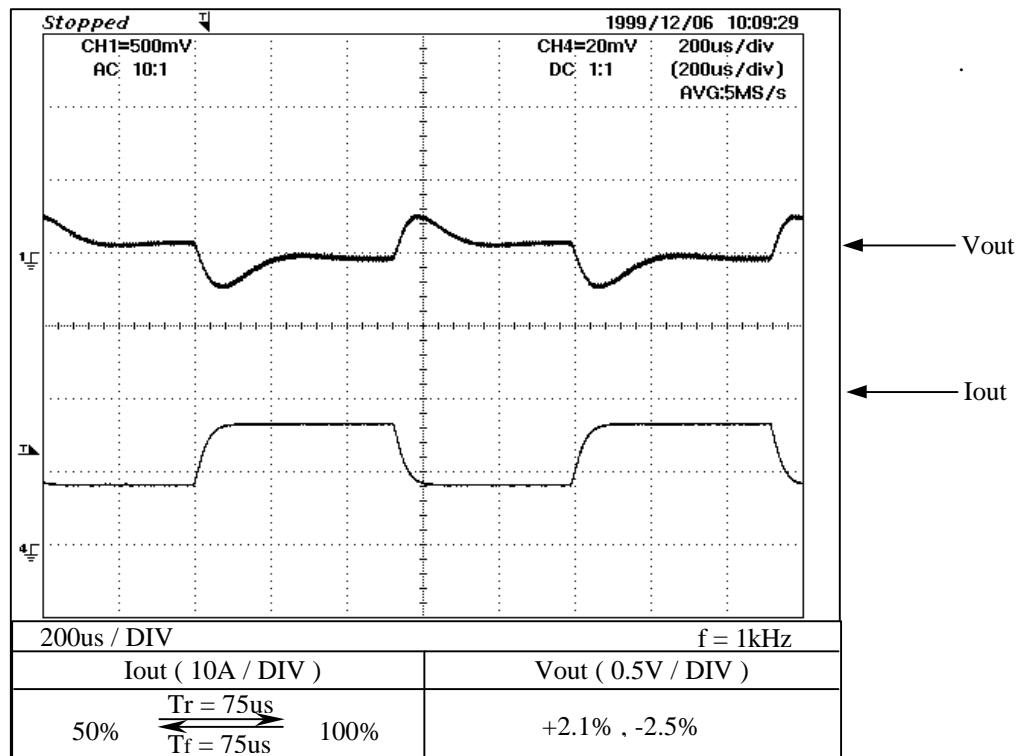
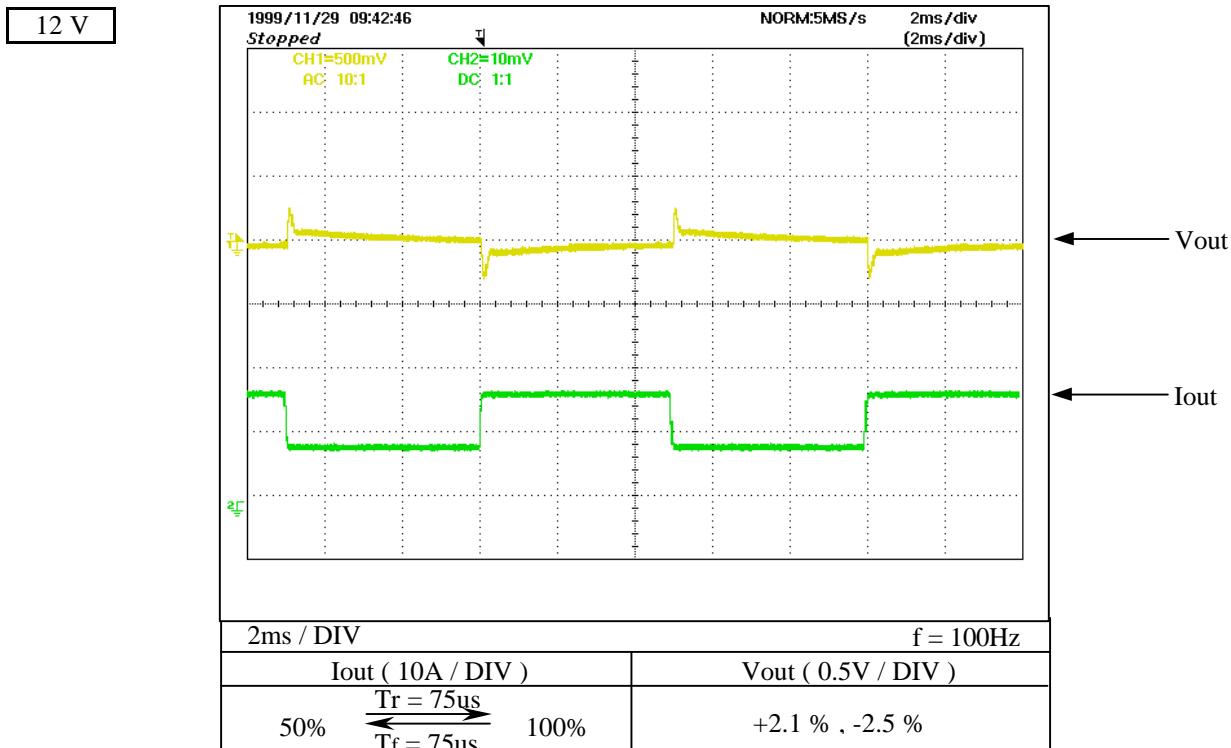


24 V



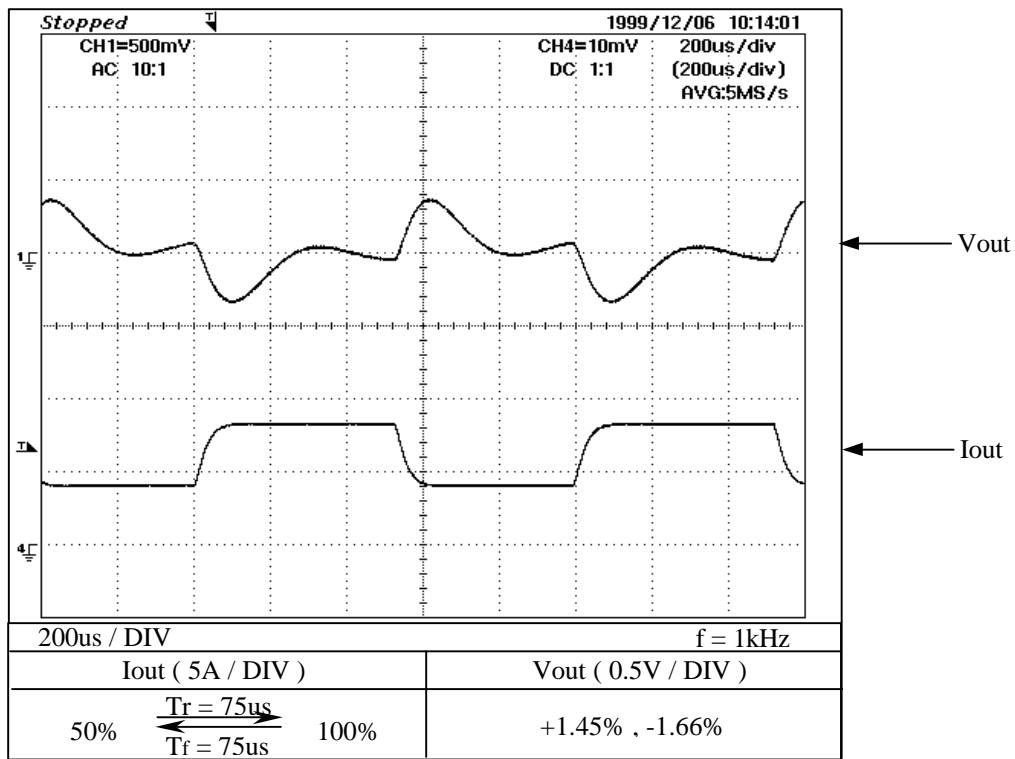
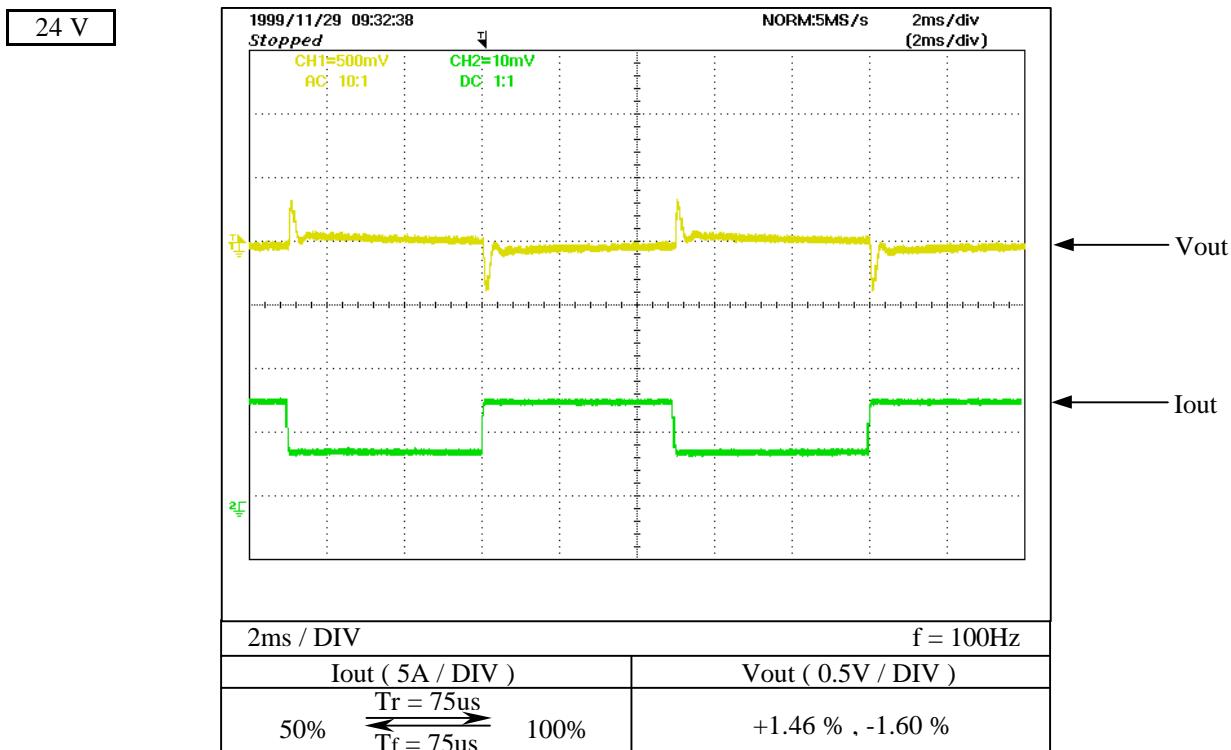
2-9 Dynamic Load Response Characteristics

Condition : Vin = 48 VDC
Tp = 25°C



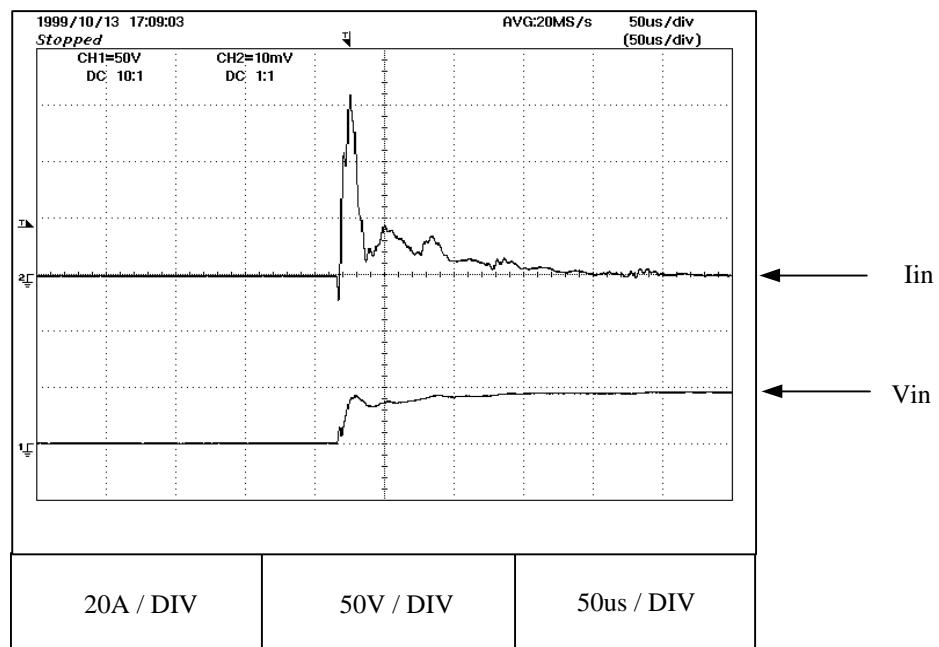
Dynamic Load Response Characteristics

Condition : Vin = 48 VDC
Tp = 25°C



2-10 Inrush Current Waveform

Condition : Vin = 48 V DC
Iout = 100 %
Tp = 25°C

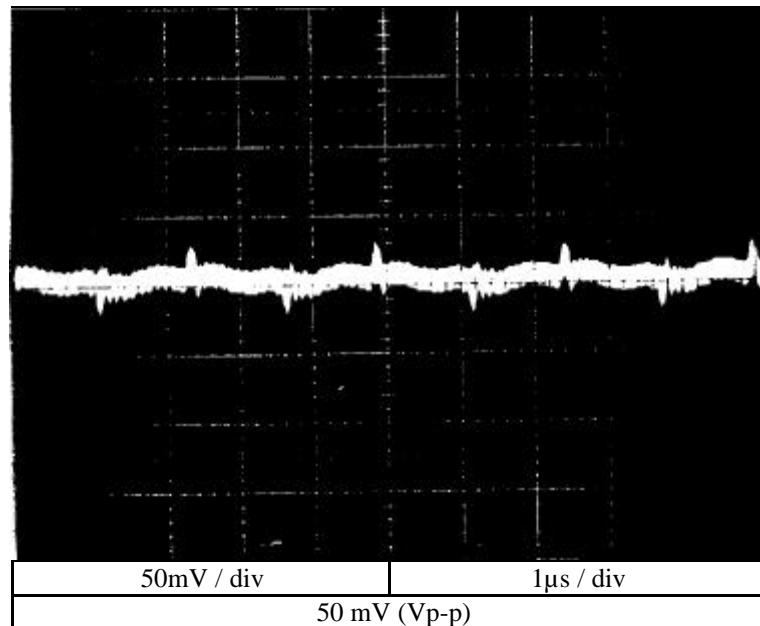


2-11 Output - Ripple & Noise Waveform

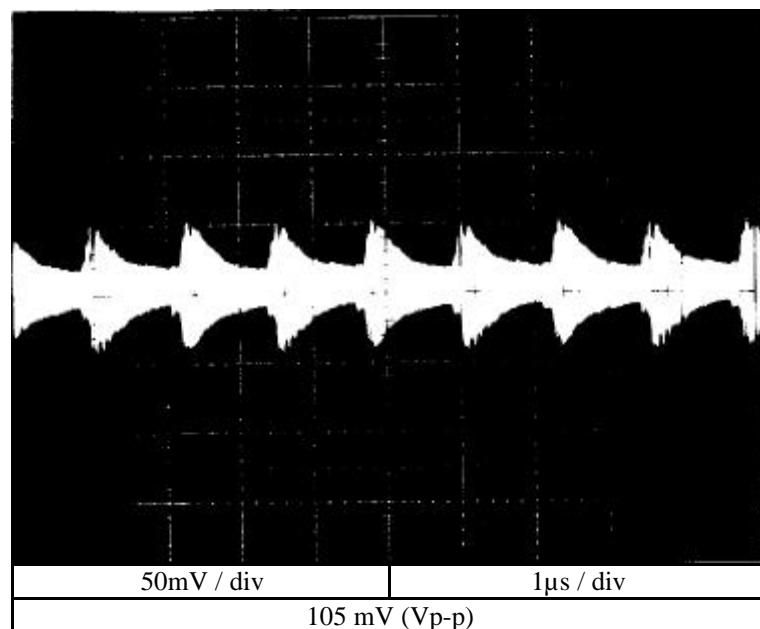
Condition : Vin = 48V DC
Iout = 100%
Tp = 25°C

12 V

NORMAL MODE



NORMAL + COMMON MODE

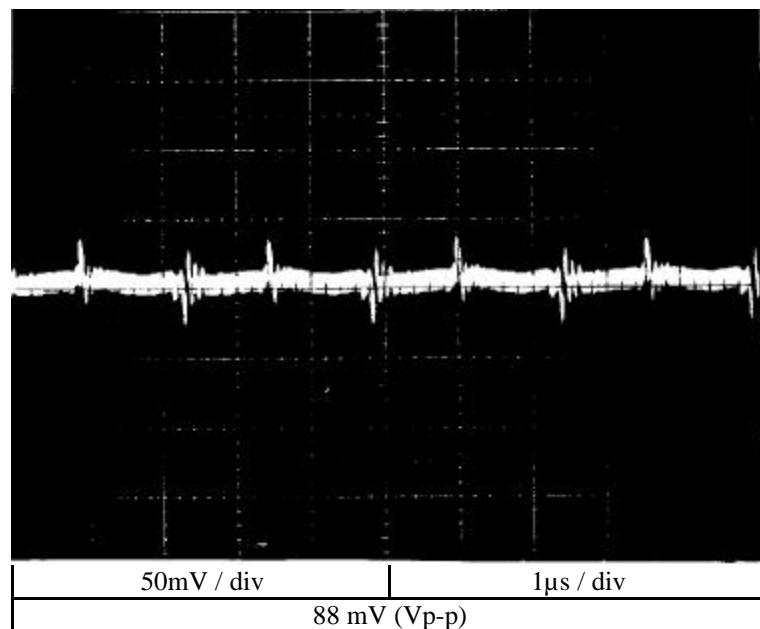


Output - Ripple & Noise Waveform

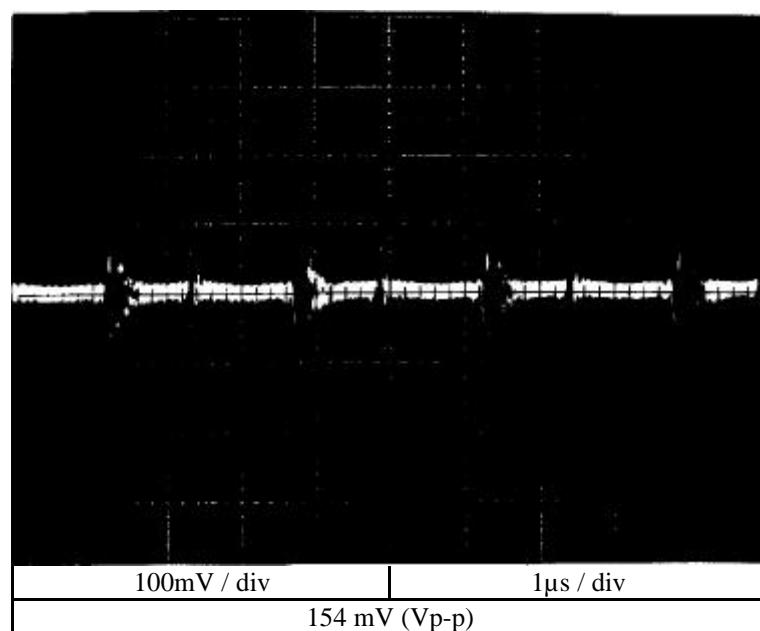
Condition : Vin = 48V DC
Iout = 100%
Tp = 25°C

24 V

NORMAL MODE

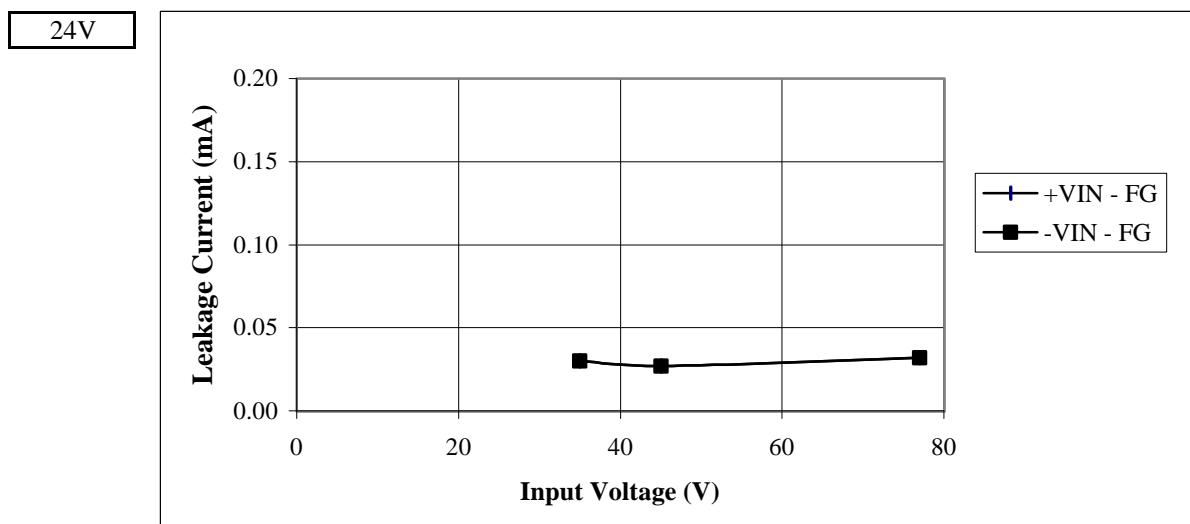
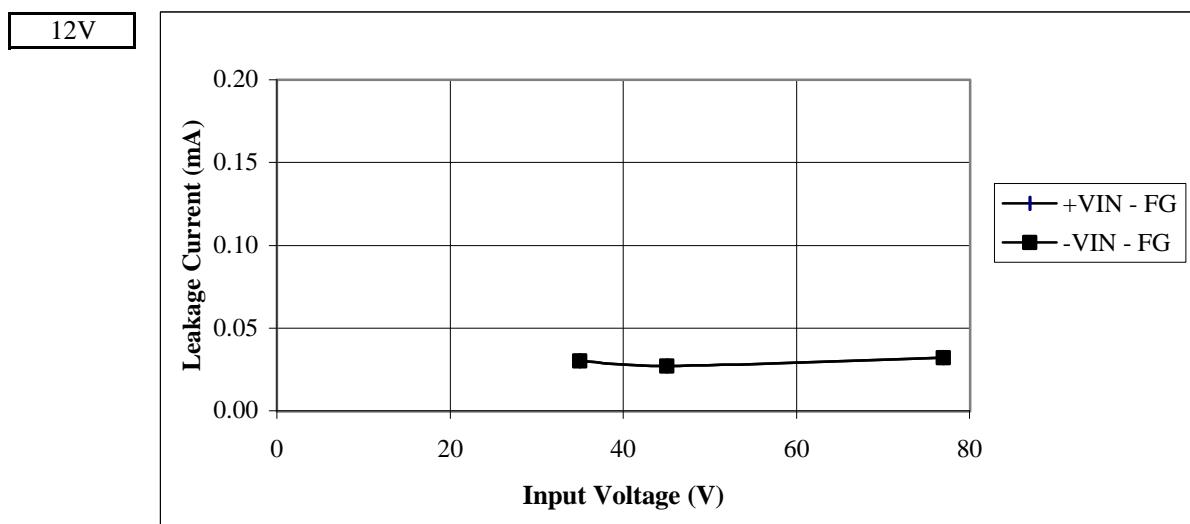


NORMAL + COMMON MODE



2-12 Leakage Current Characteristics

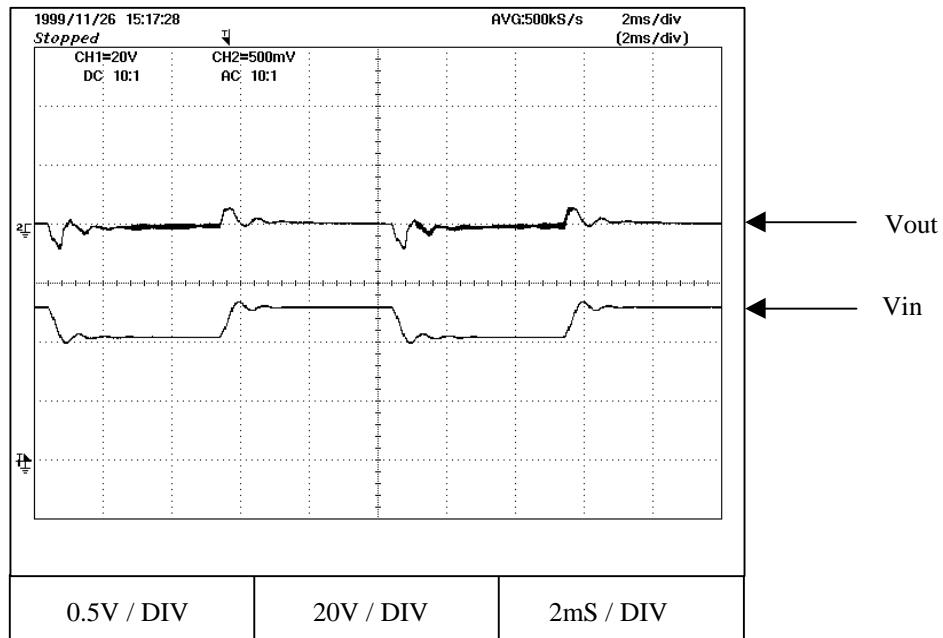
Condition : Iout = 100%
Tp= 25°C



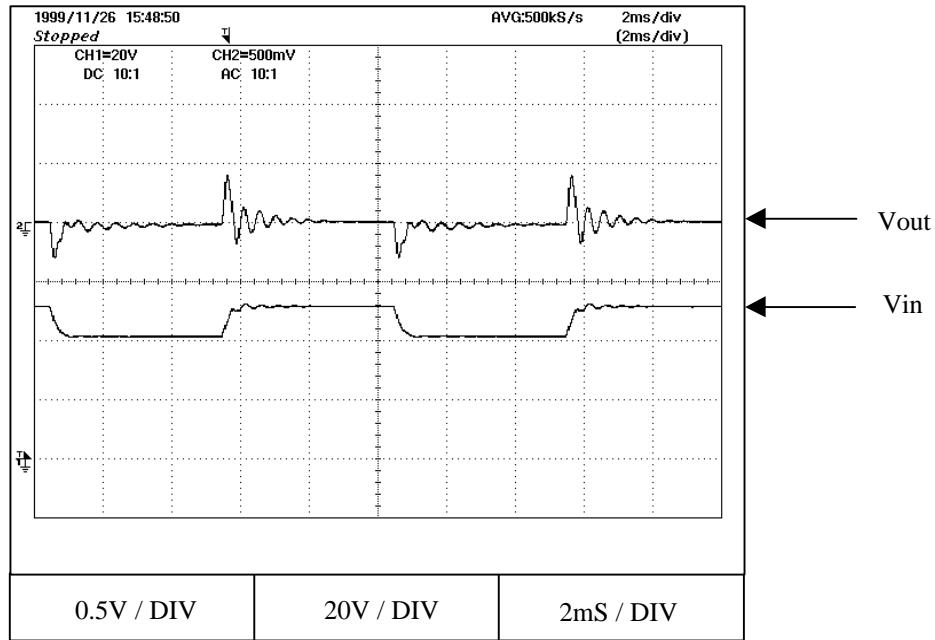
2-13 Dynamic Line Response Characteristics

Condition Vin = 43 <=> 53VDC
 Iout = 100%
 Tp= 25°C

12 V

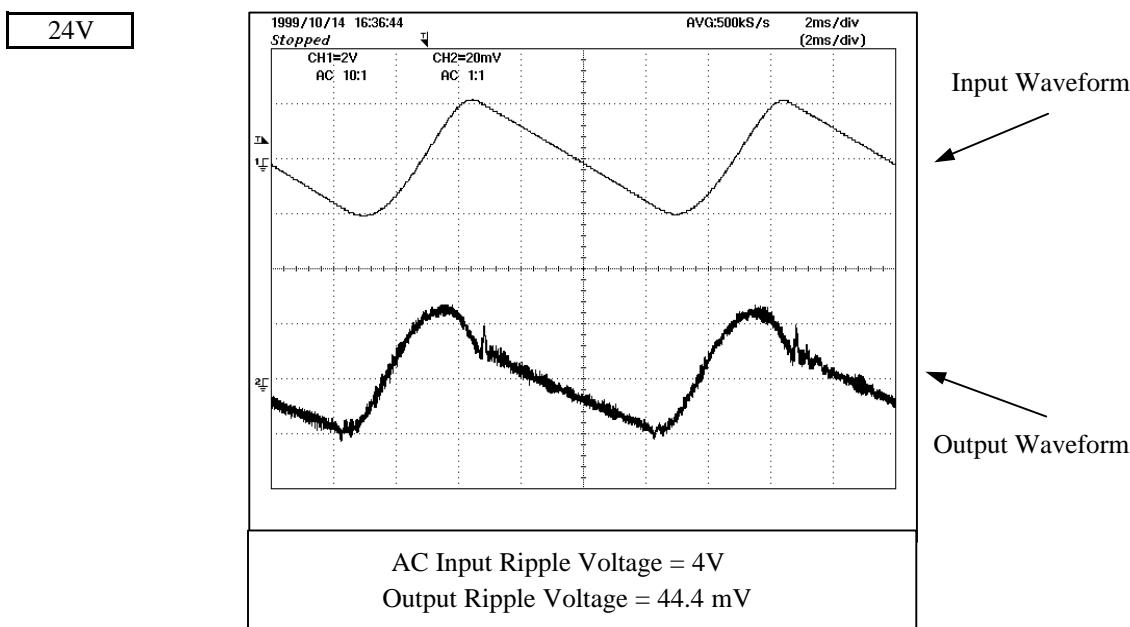
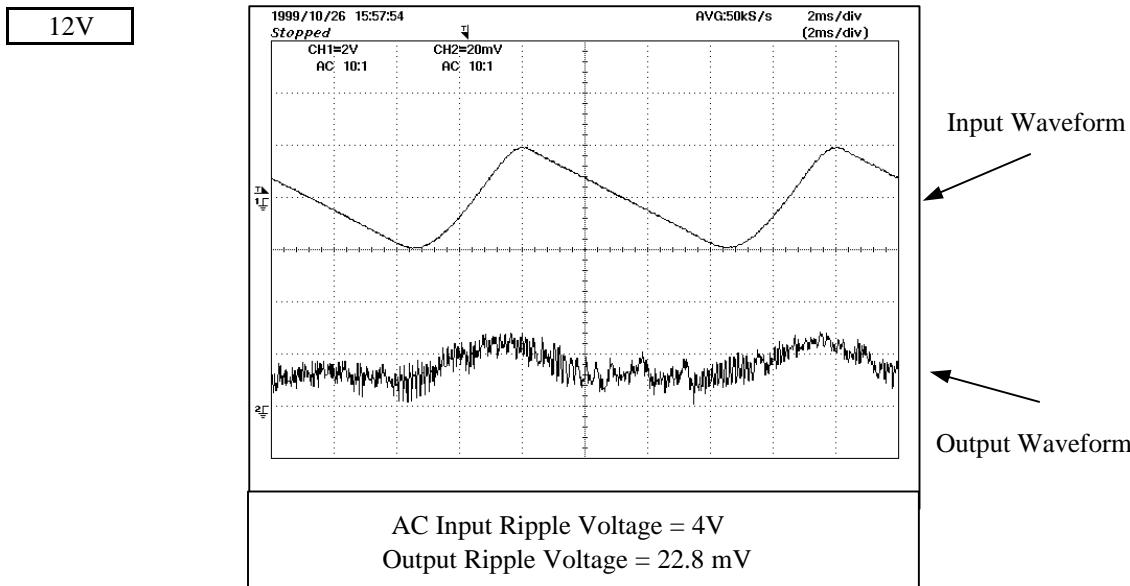


24 V



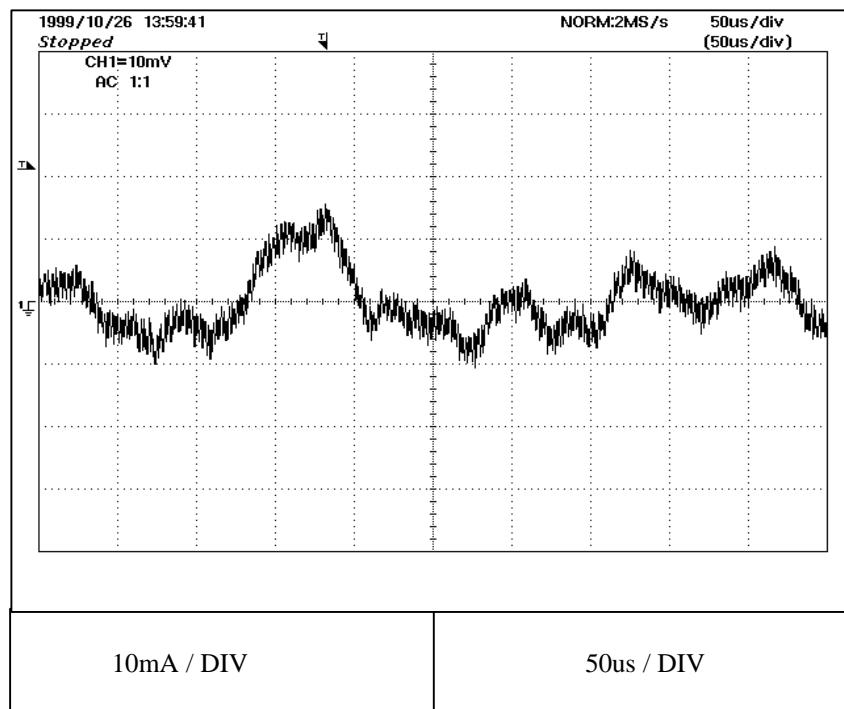
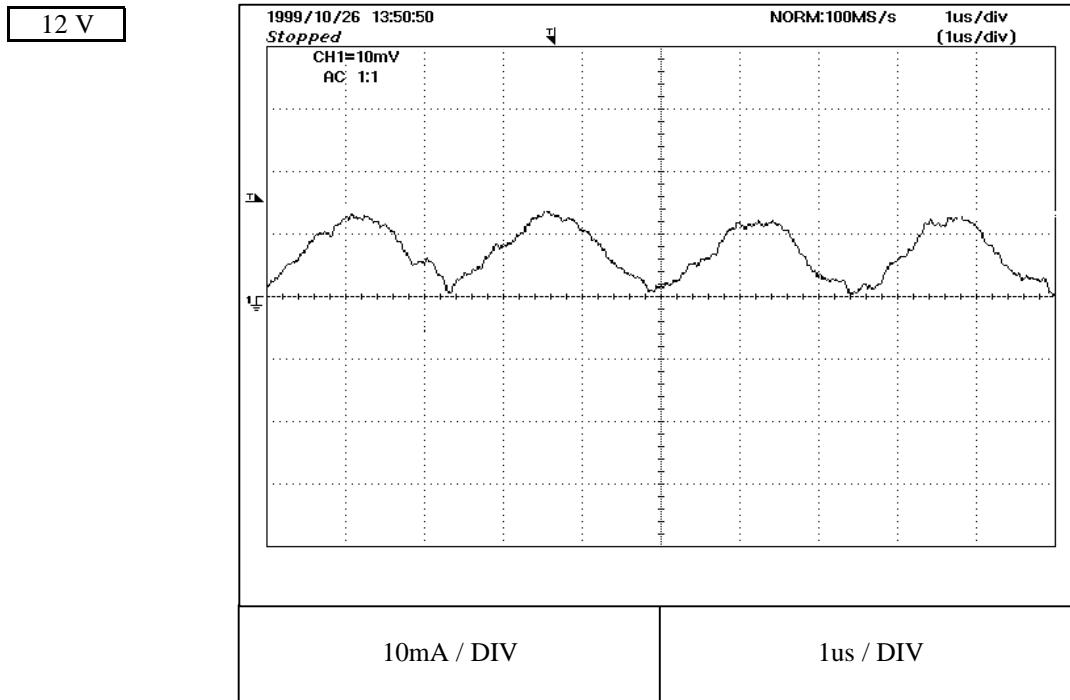
2-14 AC Input Response

Condition :
 Vin = 48 VDC
 Iout = 100%
 Tp= 25°C



2-15 INPUT REFLECTED CURRENT

Condition :
 Vin = 48 VDC
 Iout = 100%
 Tp= 25°C



2-15 INPUT REFLECTED CURRENT

Condition : Vin = 48 VDC
Iout = 100%
Tp= 25°C

